Hybrid magnon-phonon cavity for large-amplitude terahertz spin-wave excitation

Shihao Zhuang,¹ Xufeng Zhang,² Yujie Zhu,¹ Nian X. Sun,² Chang-Beom Eom,¹ Paul G. Evans,¹ and Jia-Mian $Hu\mathbf{O}^{1,'}$ $Hu\mathbf{O}^{1,'}$ $Hu\mathbf{O}^{1,'}$

1 *Department of Materials Science and Engineering, University of Wisconsin-Madison, Madison, Wisconsin, 53706, USA* ² *Department of Electrical and Computer Engineering, Northeastern University, Boston, Massachusetts 02115,*

USA

(Received 17 September 2023; revised 31 January 2024; accepted 1 March 2024; published 3 April 2024)

Terahertz (THz) spin waves or their quanta, magnons, can be efficiently excited by acoustic phonons because these excitations have similar wave vectors in the THz regime. THz acoustic phonons can be produced using photoacoustic phenomena but typically have a low population, and thus, a relatively low displacement amplitude. The magnetization amplitude and population of the acoustically excited THz magnons are thus usually small. Using analytical calculations and dynamical phase-field simulations, we show that a freestanding metal/magnetic insulator (MI)/dielectric multilayer can be designed to produce large-amplitude THz spin waves via cavity-enhanced magnon-phonon interactions. The amplitude of the acoustically excited THz spin wave in the freestanding multilayer is predicted to be more than 10 times larger than in a substrate-supported multilayer. Acoustically excited nonlinear magnon-magnon interactions are demonstrated in the freestanding multilayer. The simulations also indicate that the magnon modes can be detected by probing the charge current in the metal layer generated via spin-charge conversion across the MI/metal interface and the resulting THz radiation. Applications of the freestanding multilayer in THz optoelectronic transduction are computationally demonstrated.

DOI: [10.1103/PhysRevApplied.21.044009](http://dx.doi.org/10.1103/PhysRevApplied.21.044009)

I. INTRODUCTION

One challenge in the field of magnonics is to generate coherent magnons, quanta of spin waves with distinct wavelengths and phases, in the terahertz (THz) frequency range [\[1\]](#page-16-0). The generation of coherent THz spin waves has the potential to enable wave-based computing circuits [\[2\]](#page-16-1) with orders-of-magnitude-higher operation speed than existing gigahertz (GHz) technologies. THz spin waves, due to their nanometer (nm) scale wavelength, are dominated by Heisenberg exchange interactions and, therefore, are called exchange magnons [\[3\]](#page-16-2). Strategies for exciting such nm-scale-wavelength THz exchange magnons include establishing an external stimulus with a temporal frequency spectrum that overlaps the target THz frequencies.

Experimentally, the excitation of coherent THz exchange magnons by a pulsed THz spin current has been demonstrated in ferromagnetic metal thin films via interfacial spin-transfer torque $[4,5]$ $[4,5]$ or spin-orbit torque $[6]$. In parallel, a bulk excitation approach involves having THz acoustic phonons propagating inside the magnet and inducing coherent magnetization oscillation via magnonphonon interactions [\[7\]](#page-16-6). Since the wave number of acoustic phonons (k_{ph}) is similar to the wave number of exchange magnons (k_m) in the THz regime [\[8\]](#page-16-7), the magnon-phonon coupling strength, which is proportional to $(k_{ph}k_m)^{1/2}$, can be high [\[9\]](#page-16-8) and can lead to highly efficient magnon excitation. Experimental efforts have been pursued based on the Al(back electrode)/GaAs(substrate)/(Ga, Mn)As(film) heterostructure [\[10,](#page-16-9)[11\]](#page-16-10), in which a THz acoustic pulse is generated by femtosecond (fs)-duration optical excitation of the Al film. The acoustic pulse propagates across the GaAs substrate and induces magnetic excitation in the (Ga, Mn)As film. The frequency window of the acoustic pulse reaches up to about 0.15 THz in Ref. [\[10\]](#page-16-9) and 0.3 THz in Ref. [\[11\]](#page-16-10). Although magnon modes in the same frequency range should, in principle, be excited, the frequencies of the experimentally observed magnon modes were below 30 GHz. It appears possible that the displacement amplitude of the THz acoustic phonon modes is small in the photoinduced acoustic pulse and that, as a result, the amplitudes of the THz magnon modes could be too small to be detected using the methods reported in Refs. [\[10](#page-16-9)[,11\]](#page-16-10). Moreover, the optical penetration depth in the time-resolved magneto-optical Kerr effect (MOKE) measurements used in Refs. $[10,11]$ $[10,11]$ exceeds the nm-scale wavelength of THz spin waves. The MOKE signal is thus likely reduced because of spatial averaging over multiple spin-wave wavelengths.

^{*}jhu238@wisc.edu

Here, we computationally demonstrate that these limitations in magnon excitation and detection can be overcome by employing a hybrid magnon-photon cavity that leverages cavity-enhanced resonant magnon-phonon interactions and spin-charge conversion. Moreover, the simulations indicate that the hybrid magnon-phonon cavity structure can enable the conversion of a fs optical pulse to a nanosecond (ns) THz electric current pulse, which can potentially be exploited to achieve high-quality-factor THz optoelectronic transduction for high-data-rate wireless communication.

The proposed hybrid magnon-phonon cavity consists of a freestanding metal/magnetic insulator(MI)/dielectric multilayer, as shown in Fig. $1(a)$. This structure specifically enables the excitation of large-amplitude THz standing exchange spin waves via long-duration spatially extended resonant magnon-phonon interactions. The paramagnetic metal layer serves as both a photoacoustic transducer for generating the THz acoustic phonons via fs laser irradiation and a spin–charge-current transducer to enable the electrical detection of the acoustically excited THz magnons. Compared to all-metallic THz cavity structures, including a freestanding Ni single layer [\[12](#page-16-11)[,13\]](#page-16-12), Ni/Au bilayer, and Au/Ni/Au multilayer [\[14\]](#page-16-13), the proposed metal/MI/dielectric multilayer should have a smaller eddy-current loss, and therefore, is more suitable for high-frequency applications. From a fundamental perspective, we computationally reveal the principle of resonant magnon-phonon interactions in the freestanding multilayer using a recently developed dynamical phasefield model [\[8](#page-16-7)[,15,](#page-16-14)[16\]](#page-16-15) that incorporates nonlinear magnetoacoustic dynamics (i.e., nonlinear relations between the excited spin-wave amplitude and the driving acoustic strain), which was omitted in previous theoretical studies [\[12–](#page-16-11)[14,](#page-16-13)[17](#page-16-16)[,18\]](#page-16-17). Incorporating such nonlinearity not only enables a more accurate calculation of the magnon dynamics and population, but also allows us to model and design nonlinear magnonic devices (e.g., magnon-based recurrent neural network [\[19\]](#page-16-18) and nonlinear switches [\[20\]](#page-16-19)) with an acoustic drive.

The phase-field simulation results show that the proposed freestanding multilayer can enable frequencyselective excitation of coherent exchange-magnon modes in the 0.1–1 THz range. Comparative simulations show that the predicted amplitude of the THz standing spin wave in the freestanding multilayer is more than 10 times larger than that in a substrate-supported multilayer. For magnon detection, the simulations show that both the time-dependent electric current in the metal layer and the resultant free-space electromagnetic radiation retain spectral information of the acoustically excited THz magnon population. The simulation results also indicate that both the amplitude and frequency of the acoustically excited THz spin waves, and the resulting THz electric current, can be tuned by varying a bias magnetic field. The quality

FIG. 1. (a) Schematic of the freestanding multilayer on a substrate patterned with an air cavity at its surface. An acoustic pulse is injected into the multilayer by irradiating the metal film with a fs laser pulse. (b) Illustration of the standing longitudinal acoustic phonons, ε_{zz} , with modes of *n* in the multilayer, and standing magnons, Δm , with modes of *m* in the magnetic insulator film. J_{zj}^s is the spin-current tensor injected from the magnet/metal interface, where subscripts "*z*" and "*j*" ($=x, y, z$) refer to the direction of spin-current flow and spin polarization, respectively. J_i^c is the charge-current vector in the metal layer converted from J_{zj}^s via the inverse spin Hall effect. A bias magnetic field, **H**bias, with nonzero *z* component is applied to (1) lift the initial equilibrium magnetization off the *x*-*y* plane (for enhancing the torque from the magnetoelastic field), and (2) dynamically tune the frequencies of the ferromagnetic resonance $(m = 0$ mode magnon) and thereby higher-order magnons. Acoustically excited magnons can be detected by measuring J_i^c or the resulting THz emission.

factor of a THz optoelectronic transducer based on the present freestanding multilayer is computationally evaluated.

II. DESIGN RATIONALE

The freestanding metal/MI/dielectric multilayer, shown in Fig. $1(a)$, enables the formation of multiple harmonic modes of standing-wave acoustic phonons and magnons. The modes describing the angular wave numbers of the phonon and magnon are labeled by integer values (*n*, $m = 0, 1, 2, \ldots, \infty$, as shown in Fig. [1\(b\).](#page-1-0) The paramagnetic metal layer allows for (i) converting the incident fs optical pulse into a picosecond (ps) acoustic pulse via electron-phonon coupling and thermal expansion $[21-24]$ $[21-24]$, and (ii) converting the longitudinal spin current into a transverse charge current via the inverse spin Hall effect (ISHE) [\[25\]](#page-17-1). The excited magnon modes can be detected by measuring the THz current pulse in the metal (via a coplanar probe tip $[26]$, for frequencies up to 100 GHz) or the free-space electromagnetic (EM) radiation generated by the THz current pulse (via electro-optical sampling) [\[27\]](#page-17-3).

There are three main principles for selecting the composition of the MI component of the multilayer. First, the MI needs to have a sufficiently large magnetoelastic coupling to enable a high magnon-phonon coupling strength [\[9\]](#page-16-8). Second, the MI needs to have a high effective spinmixing conductance to inject a large spin current into the adjacent metal layer. Third, the MI layer needs to have a low effective magnetic damping coefficient, which is the sum of the Gilbert damping and other extrinsic contributions, such as two-magnon scattering and spin pumping at the MI/metal interface [\[28\]](#page-17-4). A low effective magnetic damping yields a larger magnetization amplitude and a longer lifetime for the magnon. The composition of the metal layer is selected to ensure an efficient photoacoustic transduction and a spin-to-charge conversion for magnon detection. The role of the dielectric layer in the multilayer stack is to provide additional mechanical support for the metal/MI bilayer. Direct integration of the metal/MI bilayer onto a patterned substrate, which enables concentrating a larger portion of the standing acoustic wave in the MI layer, would otherwise be preferred. All layers are best to have low elastic damping to extend the lifetime of the driving acoustic phonons.

It is challenging to find MI and metal materials that simultaneously meet these requirements. Here,

we use a freestanding $Pt/MgAl_{0.5}Fe_{1.5}O₄(001)/SiN$ multilayer to illustrate the physical principles. The $MgAl_{0.5}Fe_{1.5}O₄(001)$ (MAFO) layer is selected because it has a relatively large magnetoelastic coupling coefficient $(B_1=1.2 \text{ MJ m}^{-3})$ and a low Gilbert damping ($\alpha^0 = 0.0015$) for uniform spin precession, or the $m = 0$ mode magnon) at room temperature [\[29\]](#page-17-5). Additionally, a large spin Hall angle ($\theta_{Pt} \sim 0.83$) was previously measured at room temperature for Pt in a MAFO/Pt bilayer [\[30\]](#page-17-6), which would result in a high-efficiency spin-to-charge conversion. Other promising MI materials include (i) yttrium iron garnet, which has an ultralow Gilbert damping ($\alpha^{0} \sim 8 \times 10^{-5}$ [\[31\]](#page-17-7)) but weak magnetoelastic coupling $(B_1=0.3 \text{ MJ m}^{-3})$. $B_2= 0.55$ MJ m⁻³ [\[16\]](#page-16-15)) at room temperature; (ii) the rare-earth iron garnet $Tb_3Fe_5O_{12}$ (TbIG), which has a high magnetoelastic coupling $(B_1 = -283.32 \text{ MJ m}^{-3})$, $B_2 = -499.815 \text{ MJ m}^{-3}$ at cryogenic temperature (4.2 K) [\[32\]](#page-17-8) and a moderate room-temperature Gilbert damping $(\alpha^{0} = 0.01 - 0.02$, extrapolated from measurements of similar $Tm_3Fe_5O_{12}$ films and $Tm_3Fe_5O_{12}/Pt$ bilayers [\[33\]](#page-17-9)).

III. ANALYTICAL CALCULATIONS

By solving a set of linearized elastodynamic equations under appropriate boundary conditions (see Appendix \overline{A}), we derive an analytical formula for the frequencies of the standing acoustic phonon modes in a freestanding Pt/MAFO/SiN multilayer as a function of the thickness of the individual layers. The formula is

$$
c_{\text{Pt}}c_{\text{SiN}}\left(-1+e^{(2\text{i}d_{\text{Pt}}\omega_{n}/v_{\text{Pt}})}\right)\left(-1+e^{(2\text{i}d_{\text{MAFO}}\omega_{n}/v_{\text{MAFO}})}\right)\left(-1+e^{(2\text{i}d_{\text{SiN}}\omega_{n}/v_{\text{SiN}})}\right)v_{\text{MAFO}}^{2} + c_{\text{MAFO}}^{2}\left(1+e^{(2\text{i}d_{\text{Pt}}\omega_{n}/v_{\text{Pt}})}\right)\left(-1+e^{(2\text{i}d_{\text{MAFO}}\omega_{n}/v_{\text{MAFO}})}\right)\left(1+e^{(2\text{i}d_{\text{SiN}}\omega_{n}/v_{\text{SiN}})}\right)v_{\text{Pt}}v_{\text{SiN}} + c_{\text{MAFO}}c_{\text{SiN}}\left(1+e^{(2\text{i}d_{\text{Pt}}\omega_{n}/v_{\text{Pt}})}\right)\left(1+e^{(2\text{i}d_{\text{MAFO}}\omega_{n}/v_{\text{MAFO}})}\right)\left(-1+e^{(2\text{i}d_{\text{SiN}}\omega_{n}/v_{\text{SiN}})}\right)v_{\text{Pt}}v_{\text{MAFO}} + c_{\text{Pt}}c_{\text{MAFO}}\left(-1+e^{(2\text{i}d_{\text{Pt}}\omega_{n}/v_{\text{Pt}})}\right)\left(1+e^{(2\text{i}d_{\text{MAFO}}\omega_{n}/v_{\text{MAFO}})}\right)\left(1+e^{(2\text{i}d_{\text{SiN}}\omega_{n}/v_{\text{SiN}})}\right)v_{\text{MAFO}}v_{\text{SiN}} = 0,
$$
\n(1)

where d_{matter} , c_{matter} , and v_{matter} (mater = Pt, MAFO, SiN) refer to the thickness, elastic stiffness component c_{11} , and longitudinal sound speed of the individual layer, respectively, and ω_n is the angular frequency of the standingwave acoustic phonon modes, with $n = 1, 2, 3, \ldots, \infty$. A list of symbols for the main physical quantities used here is provided in the Supplemental Material [\[34\]](#page-17-10). The first nonzero nontrivial solution of Eq. [\(1\)](#page-2-0) yields the angular frequency value of the $n = 1$ acoustic phonon mode $(\omega_{n=1})$, and so forth for the higher-order modes. Equation [\(1\)](#page-2-0) can be applied to a freestanding bilayer (single layer) by setting zero thickness for one (two) layer(s). When the thickness of one layer is set to zero, Eq. (1) is reduced to an expression for a bilayer that is equivalent to that provided in Ref. [\[14\]](#page-16-13).

Previously, Zhuang and Hu derived the dispersion relation of the exchange magnons where the initial equilibrium magnetization vector, m⁰, can align along any direction, i.e., $f = (\gamma/2\pi)\sqrt{D^2k_m^4 + \Omega Dk_m^2 - \Lambda}$ [\[15\]](#page-16-14). For standing-wave magnon modes, the angular wave number, $k_m = m\pi/d_{\text{MAFO}}$ ($m = 0, 1, 2, \ldots, \infty$), depends on the MAFO layer thickness, d_{MAFO} . Here, the exchange stiffness is $D = 2A_{ex}/\mu_0 M_s$, where A_{ex} is the exchange coupling coefficient and M_s is the saturation magnetization; γ is the gyromagnetic ratio and μ_0 is the vacuum permeability; and Ω and Λ are functions of the initial

FIG. 2. Analytically calculated frequencies of the standing $m = 1$ and $m = 2$ magnon modes and the $n = 1, 2, \ldots, 8$ acoustic phonon modes, as a function of the magnetic insulator (MAFO) film thickness, d_{MAFO} . Thicknesses for the Pt and SiN layers are fixed and indicated by the numbers in parentheses with a unit of nm. Another inset indicates the tilted initial equilibrium magnetization \mathbf{m}^0 , with $\theta = \varphi = 45^\circ$ in this calculation.

equilibrium magnetization vector, \mathbf{m}^0 , and bias magnetic field, H^{bias} . Detailed formulae for Ω and Λ are given in Appendix [B.](#page-10-0) In this study, we consider the case in which **m**⁰ is 45° off the [110] direction ($\theta = \varphi = 45$ °, see the inset of Fig. [2\)](#page-3-0), which maximizes the torque from the effective magnetoelastic field [\[8\]](#page-16-7). Figure [2](#page-3-0) shows the frequencies of the standing acoustic phonons, $m = 1$, and the $m = 2$ mode standing magnon as a function of d_{MAFO} , where d_{Pt} and d_{SiN} are fixed at 6.6 and 31.5 nm, respectively. When the frequency of the $m = 1$ (or $m = 2$) magnon mode is equal to the frequency of the driving acoustic phonon mode, as indicated by the circles, the magnon mode can be resonantly excited. Since the fs-laser-induced acoustic pulse has a broad temporal frequency spectrum, the excitation of the $m = 2$ magnon mode would occur simultaneously with the excitation of both $m = 1$ and $m = 0$ magnon modes. For simplicity, we focus on resonant, selective excitation of the $m = 1$ magnon mode by keeping the frequency window of the injected acoustic pulse below the frequency of the $m = 2$ magnon mode [\[15\]](#page-16-14).

IV. DYNAMICAL PHASE-FIELD SIMULATIONS

To simulate the acoustic excitation of magnons and the resulting spin-charge conversion in the freestanding metal/MI/dielectric multilayer in a coupled fashion, we employ the recently developed dynamical phase-field model that incorporates the coupled dynamics of acoustic phonons, magnons, photons, and plasmons $[8,15,16]$ $[8,15,16]$ $[8,15,16]$. The photons (EM waves) result from both the precessing magnetization in the MI (via magnetic dipole radiation) and the oscillating charge-current density in the metal (via electric dipole radiation). The magnetic field component of the EM waves will affect—albeit not significantly in this case—the magnetization dynamics in the MI layer. Furthermore, since the emitted EM wave can induce a large eddy current density $(\mathbf{J}^{\mathrm{p}})$ in the metal layer, \mathbf{J}^{c} in the metal layer is the sum of both **J**ISHE (the contribution from the spin-charge conversion via the ISHE) and J^p . By coupling the dynamics of plasmons in the metal with the photon dynamics, both J^c and the EM wave can be accurately simulated [\[15\]](#page-16-14).

In our dynamical phase-field model, the Landau-Lifshitz-Gilbert (LLG) equation is used to describe the temporal evolution of the normalized magnetization, **, in the MI layer:**

$$
\frac{\partial \mathbf{m}}{\partial t} = -\frac{\gamma}{1+\alpha^2} \mathbf{m} \times \mathbf{H}^{\text{eff}} - \frac{\alpha \gamma}{1+\alpha^2} \mathbf{m} \times (\mathbf{m} \times \mathbf{H}^{\text{eff}}), \qquad (2)
$$

where α is the effective magnetic damping coefficient of the MI layer. In the proposed structure, $\alpha = \alpha^0 + \alpha^s$, where α^0 is the Gilbert damping coefficient for the $m = 0$ mode magnon, and $\alpha^s = (g\mu_B/4\pi M_s)G_{\text{eff}}^{\uparrow\downarrow}(1/d)$ [\[35\]](#page-17-11) describes the magnetic damping induced by spin pumping from the metal/MI interface into the paramagnetic metal. Here, $g = 2.05$ is the *g* factor [\[29\]](#page-17-5), μ_B is the Bohr magneton, and $G_{\text{eff}}^{\uparrow\downarrow}$ is the real part of the effective spin-mixing conductance. The total effective magnetic field, $\mathbf{H}^{\text{eff}} = \mathbf{H}^{\text{anis}} + \mathbf{H}^{\text{exch}} + \mathbf{H}^{\text{dip}} + \mathbf{H}^{\text{bias}} + \mathbf{H}^{\text{mel}} + \mathbf{H}^{\text{EM}}$, is the sum of the magnetocrystalline anisotropy field, **H**anis; the magnetic exchange coupling field, **H**exch; the magnetic dipolar coupling field, **H**dip; the bias magnetic field, **H**bias; the magnetoelastic field, **H**mel; and the magnetic field component, **H**EM, of the EM wave. Expressions for **H**anis and the **H**dip, which are both are a function of **m**, and **H**exch, a function of ∇^2 **m**, can be found in Ref. [\[15\]](#page-16-14). **H**^{bias} is applied to stabilize the initial equilibrium magnetization, \mathbf{m}^0 , to be 45° off the [110] direction, as mentioned in Sec. [III.](#page-2-1) **H**mel is a function of **m** and local strain, *ε*, given by [\[15\]](#page-16-14)

$$
H_i^{\text{mel}} = -\frac{2}{\mu_0 M_s} [B_1 m_i \varepsilon_{ii} + B_2 (m_j \varepsilon_{ij} + m_k \varepsilon_{ik})], i, j
$$

= $x, y, z; j \neq i, k \neq i, j.$ (3)

It is noteworthy that the LLG equation $[Eq. (2)]$ $[Eq. (2)]$ is intrinsically nonlinear, e.g., the frequency of magnetic excitation can double the frequency of the driving effective field when the amplitude of magnetic excitation is sufficiently large. Such nonlinearity can be analytically understood based on the conservation of magnetization vector length (i.e., $m_x^2 + m_y^2 + m_z^2 = 1$) and the method of successive approximation (see details in Ref. [\[36\]](#page-17-12)).

The local strain, *ε*, is

$$
\varepsilon_{ij} = \frac{1}{2} \left(\frac{\partial u_i}{\partial j} + \frac{\partial u_j}{\partial i} \right) (i, j = x, y, z).
$$

The evolution of the mechanical displacement, **u**, is governed by the elastodynamics equation:

$$
\rho \frac{\partial^2 \mathbf{u}}{\partial t^2} = \nabla \cdot (\boldsymbol{\sigma} + \beta \frac{\partial \boldsymbol{\sigma}}{\partial t}), \qquad (4)
$$

where stress is $\sigma = c(\epsilon - \epsilon^0)$; ρ , β , and **c** are the mass density, stiffness damping coefficient, and elastic stiffness coefficient, respectively. The stress-free magnetostrictive strain, $\boldsymbol{\varepsilon}^0$, is

$$
\varepsilon_{ii}^0 = \frac{3}{2} \lambda_{100}^{\text{M}} \left(m_i^2 - \frac{1}{3} \right),
$$

$$
\varepsilon_{ij}^0 = \frac{3}{2} \lambda_{111}^{\text{M}} m_i m_j,
$$

with $i, j = x, y, z$, where λ_{100}^M and λ_{111}^M are the magnetostrictive coefficients of the MI layer (assuming cubic symmetry). To model the injection of a fs-laser-induced psduration acoustic pulse, a Gaussian-shaped stress pulse, $\sigma_{zz}(z = d_{\text{MAFO}} + d_{\text{Pt}}, t) = \sigma_{\text{max}} \exp[-t^2/2\tau^2]$, is applied at the top surface of the Pt layer, where σ_{max} is the peak magnitude of the applied stress and τ is a free parameter that controls the pulse duration. Varying these two parameters allows us to tune the peak amplitude and frequency window of the acoustic pulse injected into Pt. Based on existing experiments, the frequency window of such a fslaser-induced acoustic pulse is typically in the sub-THz range $[10,11]$ $[10,11]$ but covers up to nearly 3 THz $[37]$; the peak strain amplitude is typically in the order of 10^{-3} [\[22,](#page-16-21)[23](#page-17-14)[,37\]](#page-17-13) but can reach 1% [\[38\]](#page-17-15).

The EM wave is described by Maxwell's equations. The two governing equations for the magnetic and electric field components are

$$
\nabla \times \mathbf{E}^{\text{EM}} = -\mu_0 \left(\frac{\partial \mathbf{H}^{\text{EM}}}{\partial t} + \frac{\partial \mathbf{M}}{\partial t} \right),\tag{5}
$$

$$
\nabla \times \mathbf{H}^{\text{EM}} = \varepsilon_0 \varepsilon_r \frac{\partial \mathbf{E}^{\text{EM}}}{\partial t} + \mathbf{J}^{\text{f}} + \mathbf{J}^{\text{p}} \,, \tag{6}
$$

where E^{EM} is the electric field component of the EM wave; $M = M_s$ **m** is the local magnetization in the MI layer, and **m** is obtained by solving the LLG equation [Eq. [\(2\)\]](#page-3-1); ε_0 and ε_r are vacuum and relative permittivities, respectively; **J^f** and **J**^p are the free current density and polarization current density, respectively, in the metal. J^p is induced by the electric field, E^{EM} , in the dispersive medium, such as metallic Pt, which leads to the absorption and reflection of the EM wave. **J**^p is obtained by solving a time-dependent auxiliary differential equation based on the Drude model:

$$
\frac{\partial \mathbf{J}^{\mathrm{p}}}{\partial t} + \frac{\mathbf{J}^{\mathrm{p}}}{\tau_{\mathrm{e}}} = \varepsilon_0 \omega_{\mathrm{p}}^2 \mathbf{E}^{\mathrm{EM}},\tag{7}
$$

where ω_p and τ_e are the plasma frequency and electron relaxation time in the metal, respectively.

These coupled equations of motion for **M**, **u**, EM fields, and J^p are numerically solved in a one-dimensional (1D) simulation system consisting of Pt/MAFO/SiN with free space above and below the multilayer. The physical quantities describing the system only vary along the *z* axis. To demonstrate that the use of a 1D system is a reasonable approximation, we built a two-dimensional (2D) multiphase system, as shown in Fig. $1(a)$, and simulated the evolution of the distributions of the acoustic phonons and magnons after acoustic pulse injection. It is found that both the acoustic phonons and magnons have the same amplitude and phase within the *x*-*y* plane, with nonuniformity only arising near the lateral surfaces of Pt and MAFO, as shown in Appendix [C.](#page-11-0)

Since the local magnetization, **m**, is spatially uniform in the *x*-*y* plane, the free current density, J^f , in the Pt layer, which is converted from the spin current density, J^s , via the ISHE ($J^f = J^{\text{ISHE}}$), is also spatially uniform in the *x*-*y* plane. The spin current density, $\mathbf{J}^{s,0}(t) = \mathbf{J}^{s}(z = d_{\text{MAPO}}, t)$, at the MAFO/Pt interface is calculated via [\[39\]](#page-17-16)

$$
\mathbf{e}_{n} \cdot \mathbf{J}^{s,0} = \frac{\hbar}{4\pi} G_{\text{eff}}^{\uparrow \downarrow} \left(\mathbf{m} \times \frac{\partial \mathbf{m}}{\partial t} \right), \tag{8}
$$

where e_n is the unit vector normal to the MAFO/Pt interface and points to Pt, i.e., $\mathbf{e}_n = [0,0,1]$; iy \overrightarrow{A} is the reduced Planck constant. Note that $J^s = J_{ij}^s$ is a second-rank tensor, where the subscript "*i*" refers to the direction of the spin-current flow and "*j*" denotes the direction of spin polarization [\[40\]](#page-17-17). Thus, $\mathbf{e}_n \cdot \mathbf{J}^{s,0} = J_{zj}^{s,0}$. The spin current density in the Pt layer, $J_{zj}^s(z, t)$, decays as a function of the distance from the MAFO/Pt interface $(z = d_{\text{MAFO}})$:

$$
J_{zj}^s(z,t) = J_{zj}^{s,0}(t) \frac{\sinh[(d_{\text{MAFO}} + d_{\text{Pt}} - z)/\lambda_{\text{SD}}]}{\sinh(d_{\text{Pt}}/\lambda_{\text{SD}})},
$$

which is obtained by solving the 1D spin-diffusion equation under the boundary conditions of J_{zj}^s ($z = d_{\text{MAFO}}$, *t*) $= J_{zj}^{s,0}(t)$ and $J_{zj}^{s}(z = d_{\text{MAFO}} + d_{\text{Pt}}, t) = 0$ [\[35,](#page-17-11)[41\]](#page-17-18), with d_{Pt} indicating the thickness of the Pt layer, and λ_{SD} is the spin-diffusion length in Pt. **J**iSHE in the Pt layer is calculated based on $\mathbf{J}^{\text{ISHE}}(z, t) = \theta_{\text{Pt}}(2e/\hbar)\mathbf{e}_{\text{n}} \times$ $J_{zj}^s(z, t)$, where θ_{Pt} is the spin Hall angle of Pt and *e* is the elementary charge. Specifically, $J_x^{\text{ISHE}}(z, t) =$ $-\theta_{\text{Pt}}(2e/\hbar)J_{zy}^{\text{s}}(z,t)$, $J_{y}^{\text{ISHE}}(z,t) = \theta_{\text{Pt}}(2e/\hbar)J_{zx}^{\text{s}}(z,t)$, and $J_z^{\text{ISHE}}(z, t) = 0$. Equation [\(8\)](#page-4-0) and the formulae of $\mathbf{J}^{\text{ISHE}}(z, t)$ together indicate that magnons of higher frequency but smaller amplitude of magnetization variation can still induce a larger peak spin current density and resulting ISHE charge-current density (see the detailed analysis in Appendix D). For the MAFO/Pt interface [30], the effective spin-mixing conductance is $G_{\text{eff}}^{\uparrow\downarrow} = 3.36 \times 10^{18} \text{ m}^{-2}$, the spin-diffusion length in Pt is $\lambda_{SD} = 3.3$ nm, and the spin Hall angle of Pt is $\theta_{\text{Pt}}= 0.83$.

When irradiating the Pt film with a fs laser pulse, the temperature difference between the phonons of MAFO and the electrons of Pt can also lead to the injection of spin current into Pt via the interfacial spin Seebeck effect [\[42–](#page-17-19)[45\]](#page-17-20). However, such a thermally pumped spin current remains significant typically for tens of ps after fs laser excitation $[46]$, which is 1–2 orders of magnitude shorter than the lifetime of the spin current from acoustic spin pumping $(10^{-10} - 10^{-9}$ s, as shown in Sec. [V\)](#page-5-0). Therefore, thermal spin pumping is not modeled herein for simplicity. The other material parameters used for simulations are listed in Appendix [E.](#page-13-0) The numerical methods for solving the LLG, elastodynamic, and Maxwell's equations are described in Appendix [F.](#page-13-1)

V. RESONANT ACOUSTIC EXCITATION OF THz MAGNONS BY DYNAMICAL PHASE-FIELD SIMULATIONS

Figure [3\(a\)](#page-5-1) shows the evolution of strain, $\varepsilon_{zz}(t)$, at the MAFO/Pt interface of the freestanding Pt(6.64 nm)/MAFO (12.45 nm)/SiN(31.54 nm) multilayer and a substratesupported multilayer of Pt(6.64 nm)/MAFO(12.45 nm)/ SiN. In the latter structure, the absorbing boundary condition is applied on the bottom surface of SiN to make it a perfect acoustic sink (see details in Appendix [F\)](#page-13-1). The two parameters determining $\sigma_{zz}(t)$ (see Sec. [IV\)](#page-3-2) are selected to be $\sigma_{\text{max}} = 3$ GPa and $\tau = 1.5$ ps; this leads to an acoustic spectrum covering up to 300 GHz and a peak strain pulse, $\varepsilon_{zz}(t)$, amplitude of 0.85% in Pt. As shown in Fig. [3\(a\),](#page-5-1) $\varepsilon_{zz}(t)$ consists of multiple cycles of acoustic oscillation that persist for more than 1 ns in the freestanding multilayer. The acoustic frequency spectrum [Fig. $3(b)$] displays three peaks at 67, 154, and 240 GHz, which agree well with the analytically calculated frequencies of the $n = 1, 2, 3$ acoustic phonon modes, respectively. In contrast, $\varepsilon_{zz}(t)$ exhibits a single cycle of oscillation that persists for only about 9 ps in the substrate-supported Pt/MAFO/SiN multilayer, and there is no peak in its frequency spectrum.

Figure $3(c)$ shows the numerically simulated change in magnetization, $\Delta m_x(t)$, at the MAFO/Pt interface of the freestanding multilayer. Its frequency spectrum, shown in Fig. $3(d)$, indicates the presence of three magnon modes at 67, 154, and 240 GHz that are induced by the $n = 1$, $n = 2$, and $n = 3$ acoustic phonon modes, respectively. Remarkably, the peak at 154 GHz has a larger spectral amplitude (i.e., larger magnon population) than the peak at 67 GHz, even though the driving 154-GHz $(n=2)$ phonon mode has a smaller spectral amplitude than the $67\text{-}GHz$ ($n=1$) phonon [cf. Fig. $3(b)$]. The large response at 154 GHz clearly indicates the resonant interaction between the driving $n = 2$ phonon mode and the $m = 1$ magnon mode. In contrast, for the substrate-supported Pt/MAFO/SiN multilayer, the temporal profile of $\Delta m_r(t)$ is dominated by a low-frequency variation corresponding to the $m = 0$ magnon mode (the ferromagnetic resonance, FMR). The simulated FMR frequency is about 0.5 GHz, see the inset

FIG. 3. Evolution of (a) strain $\varepsilon_{zz}(t)$; (c) normalized magnetization change, $\Delta m_x(t) = m_x(t) - m_x(t=0)$; and (e) charge-current density, $J_x^c(t)$, at the Pt/MAFO interface in both a freestanding Pt/MAFO/SiN and a substrate-supported Pt/MAFO/SiN(acoustic sink) multilayer. $t = 0$ is the moment the acoustic pulse is injected from the top surface of the Pt film. (b),(d),(f) Frequency spectra of $\varepsilon_{zz}(t)$, $\Delta m_x(t)$, and $J_x^c(t)$, respectively. Vertical axes are plotted on a log scale. Vertical dashed line emphasizes the resonant interaction between the $n = 2$ phonon mode and the $m = 1$ magnon mode at 154 GHz.

of Fig. [3\(d\),](#page-5-1) which agrees well with the analytically calculated value of 0.53 GHz. The 154-GHz $m = 1$ mode magnon, in this case, adds to the profile of $\Delta m_x(t)$ in the form of a small-amplitude high-frequency oscillation [see Fig. $3(c)$]. To extract the real-space amplitude of magnetization variation for the $m = 1$ mode magnon in both the freestanding and substrate-supported multilayers, we performed inverse Fourier transform of the 154-GHz peaks. As shown in Appendix [G,](#page-13-2) the amplitude of magnetization variation for the $m = 1$ magnon mode in MAFO has a maximum peak amplitude of $\Delta m_x \sim 0.082$ in the freestanding multilayer, which is 12 times larger than that in the substrate-supported multilayer.

For the freestanding multilayer, Fig. $3(d)$ also indicates the presence of multiple magnon modes that do not have counterparts in the frequency spectrum of acoustic phonons. These additional magnon modes are attributed to the acoustically excited nonlinear magnon-magnon interactions. Specifically, the effect of each standing-wave acoustic phonon mode on magnetic excitation is equivalent to the effect of applying a sinusoidal magnetic field of a distinct frequency, f_n ($n = 1,2,3...$). When the magnetization amplitudes of the acoustically excited magnon modes are sufficiently large, the nonlinearity of the LLG equation [\[36\]](#page-17-12) would lead to nonlinear effects, such as frequency mixing $(f = n_1 f_1 \pm n_2 f_2 \pm \dots, n_{1,2} = 0,1,2...)$ and frequency doubling $(f = cf_n, c = 1,2,3...)$. As shown in Fig. $3(d)$, there are three magnon modes arising from frequency mixing, all involving the resonantly excited $m = 1$

magnon mode $(f_2 = f_{m-1})$, which has a large magnetization amplitude. There is one magnon mode resulting from second-harmonic generation of the f_1 magnon mode. Notably, the $f_1 + f_2$ magnon mode, induced through the mixing of two dominant magnon modes, has a larger spectral amplitude than the linearly excited f_3 ($m = 3$) magnon mode.

Figure $3(e)$ shows the evolution of the total chargecurrent density, $J^c(z = d_{\text{MAPO}}, t)$, at the Pt/MAFO interface in the freestanding multilayer, which is the sum of the ISHE charge current, $J^{\text{ISHE}}(z = d_{\text{MAFO}}, t)$, and the polarization current, $J^p(z = d_{\text{MAFO}}, t)$. J^p has a similar temporal profile to that of **J**ISHE, but it has a smaller amplitude and is 180° out of phase (see Appendix [H\)](#page-13-3). Similarly to the profile of $\Delta m_x(t)$ in Fig. [3\(c\),](#page-5-1) the total current density, $J_x^{\text{tot}}(t)$, contains a mixture of low-frequency and high-frequency components and persists for several ns. The two dominant frequencies (67 and 154 GHz) in the frequency spectrum of the current [Fig. $3(f)$] are the same as those in the spectrum of $\Delta m_x(t)$. As shown in Fig. [3\(f\),](#page-5-1) the spectral amplitude of the 154-GHz peak is about 10 times larger than the 67-GHz peak. This enhancement is even more significant than that shown in Fig. $3(d)$, because the 154-GHz magnon leads to a larger J^{ISHE} via spin pumping [see Eq. (8)] compared to the 67-GHz magnon. The spectral information of all nonlinearly excited magnon modes is also retained in the frequency spectrum of $J_x^c(t)$. By comparison, $J_x^c(t)$ in the substrate-supported Pt/MAFO/SiN multilayer has a 1 order-of-magnitude-smaller amplitude and a much shorter lifetime. The frequency spectrum of $J_x^c(t)$ shows a single peak at 154 GHz, which corresponds to the $m = 1$ magnon mode. There are no peaks corresponding to nonlinear THz magnon modes due to the relatively small magnetization amplitudes of the acoustically excited THz magnons. The temporal profile of the electric field component, $\mathbf{E}^{\text{EM}}(t)$, of the EM wave emitted into free space, as shown in Appendix [I,](#page-14-0) is similar to that of $J_x^c(t)$. The peak amplitude of **E**EM is about 400 V m−¹ in the freestanding multilayer and about 36 V m⁻¹ in the substrate-supported multilayer. These peak electric fields are large enough for measurement by free-space electro-optical sampling [\[47\]](#page-17-22) and their frequencies (154 and 67 GHz) are also within the detectable range [\[27\]](#page-17-3). Alternatively, it may be possible to directly measure the charge current in this frequency range in the Pt layer using a coplanar probe tip followed by fs laser irradiation (known as ultrafast ISHE measurement $[26]$.

It is possible to dynamically tune the frequencies and temporal profile of J^c in the Pt layer, and hence, the freespace EM radiation, by varying the bias magnetic field. Figure $4(a)$ shows the analytically calculated frequencies (*f*) of the $m = 0$ and $m = 1$ magnon modes as a function of the magnitude of the bias magnetic field, $|\mathbf{H}^{bias}|$, in the freestanding $Pt(6.64)/MAFO(12.45)/SiN(31.54)$ multilayer. The direction of **H**bias is varied to keep the

FIG. 4. (a) Analytically calculated frequencies of the $m = 0$ and $m = 1$ magnon modes as functions of the magnitude of bias magnetic fields, H^{bias} , with the frequencies of the standing acoustic phonon modes $n = 1-5$. Circles indicate $|\mathbf{H}^{bias}|$ that leads to resonant magnon-phonon interactions. Evolution of (b) strain, $\varepsilon_{zz}(t)$, and (d) charge-current density, $J_x^c(t)$, at the Pt/MAFO interface. (c),(e) Corresponding frequency spectra where the vertical axes are plotted on a linear scale.

equilibrium magnetization 45° off the [110] direction $(\theta = \varphi = 45^{\circ})$. The frequencies of the standing acoustic phonon modes, which do not vary with the magnetic field, are plotted as horizontal lines. At $|\mathbf{H}^{bias}| = 0.087$ T (as in Fig. [3\)](#page-5-1), the $m = 1$ magnon mode has a frequency of 154 GHz, which leads to a resonant interaction with the $n = 2$ phonon mode. At $|\mathbf{H}^{bias}| = 3.02$ T, the $m = 1$ magnon mode shows an increased frequency to 240 GHz, and hence, can resonantly interact with the $n = 3$ phonon mode, and so forth.

To demonstrate resonant excitation of the $m = 1$ magnon mode by the higher-order $n = 3$ phonon mode, we inject a strain pulse with a frequency window reaching 500 GHz by setting the parameter τ in the applied stress, $\sigma_{zz}(t)$, to be 0.8 ps and keeping $\sigma_{\text{max}} = 3$ GPa the same as that in Fig. [3.](#page-5-1) The acoustically excited magnon dynamics and chargecurrent dynamics are then simulated under $|\mathbf{H}^{bias}| = 3.02$ T. Figure $4(b)$ shows the evolution of injected $\varepsilon_{zz}(t)$ at the MAFO/Pt interface. As shown by its frequency spectrum in Fig. $4(c)$, phonon modes $n = 1-5$ can all be excited, and their frequencies agree well with the analytical calculations

			$f=f_n$ (GHz)	Δf (GHz)	ϱ	$f = f_{m} = 1$ (GHz)	Δf (GHz)	Q
$d_{\rm MAFO}$ (nm)	d_{SiN} (nm)	α (magnetic damping)	Freestanding multilayer			Substrate-supported multilayer		
5.4	7.8	0.011 177 97	814.5	18.615 242 1	43.754 467 27	814.75	33.103.212.5	24.6124149
6	19.2	0.010 371 47	659.5	13.1166238	50.27970689	659.5	25.6598802	25.7016009
6.6	12.6	0.009 689 05	546	9.395 509 74	58.11286615	546	18.581 0923	29.3847095
7.2	27.3	0.008 791 62	459.25	6.930 234 04	66.267 603 29	458.75	14.0197726	32.721 643 5
8.4	29.1	0.00776222	337.5	4.12632647	81.791 880 09	337.25	9.483 856 09	35.5604299
9.6	84.9	0.007 044 67	259	2.543 337 09	101.8347121	258.75	6.3608808	40.6783287
9.9	33.3	0.00682288	243.5	2.28438056	106.593 447 8	243.5	5.809 176 86	41.9164377
10.5	39.6	0.006 618 16	216.75	1.87432642	115.641 543 6	216.5	5.01471726	43.1729226
11.4	49.5	0.006 169 2	184	1.38301841	133.0423358	184	4.00792491	45.909 043 7
12.6	63.9	0.005 658 5	150.75	0.946 466 36	159.276 658 9	150.75	3.015 103 39	49.998 285 5
15	8.4	0.005 048 59	106.75	0.493 794 16	216.183 198 1	106.75	1.945 983 41	54.856 582 9
18.6	22.8	0.004 346 46	70	0.230 742 35	303.368 668 1	69.75	1.1176789	62.406 117
21.6	129.6	0.003 964 3	52	0.134 377 17	386.9704951	52	0.779 376 14	66.720 030 6
24.9	300	0.003 6377	39.4	0.08633833	456.3442289	39.4	0.509 469 45	77.335354
27.3	78	0.003 442 66	32.75	0.060 456 72	541.709847	33	0.398 058 86	82.9023124

TABLE I. Thicknesses of the MAFO and SiN layers used in Fig. [5;](#page-8-0) the simulated resonant frequency, f ; linewidth, Δf ; and Q ($=f/\Delta f$) for both the freestanding and substrate-supported multilayers. The thickness of Pt is fixed at 6.6 nm.

via Eq. [\(1\).](#page-2-0) The evolution of total current density $J_x^c(t)$ at the MAFO/Pt interface is shown in Fig. $4(d)$. The duration of $J_x^c(t)$ is shorter than that in the case of 154 GHz [cf. Fig. $3(e)$] due to the shorter lifetime of the driving 240-GHz phonon. Remarkably, as shown in Fig. $4(e)$, the spectral amplitude of the 240-GHz magnon peak is largest, even though the 240-GHz phonon peak has a negligibly small spectral amplitude [cf. Fig. $4(c)$]. The other two frequency peaks in Fig. $4(e)$ are contributed to by the nonresonant $m = 0$ magnon (FMR) mode (86 GHz) and the nonexchange magnon mode (67 GHz) induced by the $n = 1$ phonon mode. Likewise, nonlinear magnon modes resulting from frequency mixing or doubling are also induced (see Appendix [J\)](#page-14-1).

Due to this capability of converting a fs laser pulse into a ns-lifetime charge current with oscillation frequencies over 100 GHz, the proposed freestanding multilayer can potentially be utilized to develop a dynamically tunable on-chip THz optoelectronic transducer, which can further be used to design an on-chip THz optoelectronic oscillator (OEO) for next-generation wireless communication applications. The maximum achievable operation frequency of existing OEO systems is usually below 100 GHz [\[48–](#page-17-23)[50\]](#page-17-24), for which one key limitation is the relatively low operation frequency of the optoelectronic transducer (typically a semiconductor-based photodetector) [\[48,](#page-17-23)[49](#page-17-25)[,51\]](#page-17-26). There are other approaches that permit converting a fs laser pulse into a THz charge-current pulse, including a photoconductive (Auston) switch [\[52](#page-17-27)[,53\]](#page-17-28) and spintronic THz emitter (STE) [\[54](#page-17-29)[–57\]](#page-18-0), but the THz current pulses are broadband and typically persist for at most a few ps. For comparison, we evaluated the frequency (*f*) dependence of the quality factor $(Q = f/\Delta f)$ of the freestanding multilayer. First, we perform analytical calculations (similarly to Fig. [2\)](#page-3-0) to identify d_{MAPO} and d_{SiN} (see Table [I](#page-7-0) in Appendix [K](#page-14-2) for values) that enable resonant excitation of the $m = 1$ magnon mode by acoustic phonons of different modes within the $0.03-1$ THz range. d_{Pt} is fixed at 6.6 nm. Second, dynamical phase-field simulations are performed to obtain the charge-current density at the MAFO/Pt interface for each combination of d_{MAPO} and d_{SiN} , which allows for extracting the linewidth, Δf (full width at half maximum), of the target peak frequency. For an oscillatory time-domain signal, a longer lifetime leads to a narrower linewidth, Δf , and hence, a larger Q . For further comparison, we also evaluate the *Q*-*f* relationship in the substratesupported Pt/MAFO/SiN(acoustic sink) multilayer, which also displays a multicycle charge-current pulse but with fewer cycles (hence, it should have a smaller *Q*) and a smaller amplitude.

In both the freestanding and substrate-supported multilayers, the lifetime of the charge-current pulse is determined largely by the lifetime of the acoustically excited magnons at the MAFO/Pt interface. In the freestanding multilayer that involves extended resonant magnon-phonon interactions, the magnon lifetime is determined by both elastic damping and magnetic damping, and both damping terms become more significant at higher frequencies. Specifically, the lifetime of the driving acoustic phonon ($\tau_{\rm ph}$), which can be analytically calculated as $t_{ph} = \beta / (\sqrt{1 + \omega^2 \beta^2} - 1)$, is shorter at larger ω , indicating enhanced elastic damping. Moreover, the spin-pumping-induced damping (α^s) , which is part of the

FIG. 5. Simulated quality factor, *Q*, versus resonant frequency, *f*, of the magnonic optoelectronic transducer based on both freestanding and substrate-supported multilayers. Typical *Q* values of the Auston switch and the STE, both of which permit the conversion of a fs optical pulse into a THz charge-current pulse as well. Inset illustrates the definition of *Q*. Literature sources of data points for the Auston switch and STE are provided in Ref. [\[8\]](#page-16-7).

effective magnetic damping coefficient (α) , is proportional to $1/d_{\text{MAFO}}$. To obtain the higher-frequency $m = 1$ mode magnon, a smaller d_{MAFO} needs to be used (see Fig. [2\)](#page-3-0), resulting in a more significant magnetic damping at higher operation frequencies.

As shown in Fig. [5,](#page-8-0) the *Q* of the freestanding multilayer decreases largely linearly with *f*, with a high *Qf* product of above 10 THz, which is 1-order-ofmagnitude higher than both the Auston switch and STE. To evaluate the role of elastic and magnetic damping, two control simulations were performed for the Pt(6.64 nm)/MAFO(12.45 nm)/SiN(31.54 nm) freestanding multilayer by individually setting $\beta = 0$ or $\alpha = 0$, with a resonant frequency of about 154 GHz (the same as in Fig. [3\)](#page-5-1). As shown in Appendix [L,](#page-15-0) *Q* increases from about 155 to 428 under $\alpha = 0$, while it increases to 588 under $\beta = 0$, suggesting a more substantial role of elastic damping in the freestanding multilayer. By contrast, in the substrate-supported multilayer, the lifetime of the acoustically excited magnons is largely determined by magnetic damping alone because the injected acoustic pulse only stays in the MAFO layer briefly (∼1.55 ps for a 12.5-nmthick film). For this reason, *Q* of the substrate-supported multilayer decreases less drastically with increasing *f* compared to the *Q*-*f* relation of the freestanding multilayer. Nevertheless, both *Q* and the charge-current amplitude of the freestanding multilayer, due to the resonant magnon-phonon interaction, are substantially larger than the substrate-supported multilayer, even at relatively high frequencies [similarly to those in Fig. $3(e)$].

It is also worth comparing the acoustic-to-magnetic energy-conversion efficiency of the freestanding and substrate-supported multilayers, which critically determines the overall efficiency of the THz optoelectronic transducer. The areal energy of the injected acoustic wave is evaluated using

$$
F_a = \int_0^{t_0} \left[-\frac{\partial u_z(z = z_0, t)}{\partial t} K \frac{\partial u_z(t)}{\partial z} \bigg|_{z = z_0} \right] dt
$$

in single-layer Pt, where the Gaussian-shaped stress pulse, $\sigma_{zz}(t)$, is applied to its top surface $(z=z_0)$, yet the absorbing boundary condition is applied to the bottom surface to avoid acoustic wave reflection. Here, *uz* is the mechanical displacement obtained from the simulations, *K* is the bulk modulus of Pt, and t_0 is the duration of the applied stress pulse. For a stress pulse with $\sigma_{\text{max}} = 3$ GPa and $\tau = 1.5$ ps (the same as those used in Fig. [3\)](#page-5-1), $F_a \approx 0.2256 \text{ J/m}^2$. The magnetic energy converted from the acoustic wave is evaluated by calculating the magnetic energy dissipation over the entire process of excitation and relaxation, i.e.,

$$
F^{\mathbf{m}} = \int_0^{t_1} \int_0^d \frac{\partial f(z, t)}{\partial t} dz dt,
$$

where *d* is the thickness of the magnetic layer, t_1 is the overall duration of the magnetic excitation, and the dissipation rate of the magnetic energy density is [\[39\]](#page-17-16)

$$
\frac{\partial f}{\partial t} = \frac{\partial f}{\partial \mathbf{m}} \frac{\partial \mathbf{m}}{\partial t} = -\mu_0 M_s (\mathbf{H}^{\text{anis}} + \mathbf{H}^{\text{dip}} + \mathbf{H}^{\text{bias}} + \mathbf{H}^{\text{mid}}) \frac{\partial \mathbf{m}}{\partial t}.
$$

After some algebra and omitting the contribution from **H**anis due to the relatively weak magnetocrystalline anisotropy of the MAFO, one has

$$
F^{\rm m} \approx \int_0^{t_1} \int_0^{d_{\rm MAPO}} (\mu_0 M_s^2 \Delta m_z + 2B_1 m_z \varepsilon_{zz}) \frac{\partial m_z}{\partial t} dz dt.
$$

Using the simulated **m**(*z*,*t*) and $\varepsilon_{zz}(z,t)$ in the case of Fig. [3](#page-5-1) as the input, F^{m} is calculated to be 9.26×10^{-5} Jm⁻² for the freestanding multilayer and 1.26×10^{-7} J m⁻² for the substrate-supported multilayer. Thus, the acoustic-tomagnetic energy-conversion efficiency in the freestanding multilayer (\sim 4 × 10⁻⁴) is approximately 3 orders of magnitude higher than that in the substrate-supported multilayer (∼5.6 [×] ¹⁰−7). From the analytical formula of *^F*m, the conversion efficiency in the freestanding multilayer can be further improved by (i) using a MI layer with a larger magnetoelastic coupling coefficient, B_1 , and saturation magnetization, M_s (such as TbIG [\[32\]](#page-17-8)); and (ii) optimizing the spatial profile overlap between the magnon and acoustic phonon modes such that a larger portion of $\varepsilon_{zz}(z, t)$ can be located within the MI layer (e.g., using a freestanding metal/MI bilayer) along with wave-number matching.

VI. CONCLUSIONS

We have computationally designed a hybrid magnonphonon cavity, which consists of a freestanding metal/MI/ dielectric multilayer and can enable the frequencyselective excitation of large-amplitude THz spin waves via cavity-enhanced magnon-phonon interactions. We developed an analytical formula to identify the individual layer thickness (Fig. [2\)](#page-3-0) and the bias magnetic field [Fig. $4(a)$] that led to the resonant magnon-phonon interaction. We performed dynamical phase-field simulations to model the spatiotemporal profiles of the acoustically excited magnon modes and the resulting charge-current pulse and freespace EM radiation, both of which are found to retain the spectral information of both the linearly and nonlinearly excited THz magnon modes. The simulation results suggest that it is possible to excite and detect large-amplitude THz spin waves in the proposed freestanding multilayer by ultrafast ISHE measurements or THz emission spectroscopy with a fs optical pump.

From a fundamental perspective, the proposed freestanding multilayer would be a well-suited platform for studying the damping mechanisms of magnons in the THz regime (e.g., the possible inertial effects $[58–61]$ $[58–61]$) due to the capability of enabling ns-lifetime THz magnons. Furthermore, the extended magnon-phonon interaction time in the freestanding multilayer makes it possible to realize the hybridization of magnons and phonons in the THz regime by matching both their frequency and wave number via geometrical design (see Appendix [M\)](#page-15-1).

For applications, the proposed freestanding multilayer can potentially be used to design a THz optoelectronic transducer, due to its unique capability to convert a fs laser pulse into a ns charge-current pulse with a dominant frequency peak in the 0.1–1 THz range. It has a 1-order-ofmagnitude-higher *Q* factor than previously existing technologies (Auston switch [\[52](#page-17-27)[,53\]](#page-17-28), spintronic THz emitter [\[54](#page-17-29)[–57\]](#page-18-0)) that also involve the use of a fs optical pump to generate THz current pulses. Combined with the dynamical tunability, such a high-*Q* magnonic THz optoelectronic transducer provides attractive potential for THz wireless communication [\[62\]](#page-18-3) and narrowband THz spectroscopy [\[8\]](#page-16-7) applications.

ACKNOWLEDGMENT

Support from the National Science Foundation (NSF) Awards No. CBET-2006028 (S.Z. and J.-M.H.) and No. DMR-2237884 (Y.Z. and J.-M.H.) are gratefully acknowledged. The dynamical phase-field simulations were performed using Bridges at the Pittsburgh Supercomputing Center through allocation TG-DMR180076 from the Advanced Cyberinfrastructure Coordination Ecosystem: Services & Support (ACCESS) program, which is supported by NSF Grants No. 2138259, No. 2138286, No.

FIG. 6. Schematic of an elastically heterogeneous trilayer membrane structure where mechanical displacement waves, $u(z,t)$, are propagating.

2138307, No. 2137603, and No. 2138296. X.Z. acknowledges support from ONR YIP (Grant No. N00014-23-1- 2144). P.E. acknowledges support from the U.S. Department of Energy Office of Basic Energy Sciences through Grant No. DE-FG02-04ER46147. Helpful discussions with Changchun Zhong and Wei Zhang are also acknowledged.

APPENDIX A: DERIVATION OF FREQUENCIES OF STANDING ACOUSTIC PHONON MODES IN A FREESTANDING TRILAYER

The frequencies of the acoustic standing waves are obtained by solving the system of linear equations that describe the boundary conditions of the acoustic wave. First, we consider an elastically heterogeneous trilayer structure, as shown in Fig. [6,](#page-9-1) with d_{ξ} being the thickness of each layer $\xi = A$, B, C, and assume that the mechanical displacement waves propagating in the structure only have *z* components, considering that they are produced by laser-induced thermal expansion. The solutions of the (*z*component) mechanical displacement are assumed to be the combination of the plane waves, $u_{\xi}^{+}e^{i(\omega t - k_{\xi}z)}$ propagating along $+z$ and $u_{\xi}^{-}e^{i(\omega t + k_{\xi}z)}$ along $-z$ in each layer, where u_{ξ}^{+} and u_{ξ}^{-} are the amplitudes of the wave components, ω is the angular frequency, and $k_{\xi} = \omega/v_{\xi}$ is the angular wave number with v_{ξ} being the longitudinal sound speed. With these, the out-of-plane normal strain,

$$
\varepsilon_{\xi}(z,t)=\frac{\partial u_{\xi}}{\partial z},
$$

and stress, $\sigma_{\xi}(z, t) = c_{\xi} \varepsilon_{\xi}(z, t)$, in each layer can be calculated as $ik_{\xi}[u_{\xi}^{-}e^{i(\omega t + k_{\xi}z)} - u_{\xi}^{+}e^{i(\omega t - k_{\xi}z)}]$ and $ic_{\xi}k_{\xi}[u_{\xi}^{-}e^{i(\omega t + k_{\xi}z)} - u_{\xi}^{+}e^{i(\omega t - k_{\xi}z)}]$, respectively, where c_{ξ} denotes the elastic stiffness component, c_{11} , of each layer ξ here.

The stress-free boundary condition at the bottom surface of layer A, $\sigma_A(z=0, t) = 0$, gives

$$
c_{A}k_{A}(u_{A}^{-} - u_{A}^{+}) = 0. \tag{A1}
$$

Similarly, the stress-free boundary condition at the top surface of layer *C*, $\sigma_C(z = d, t) = 0$, gives

$$
c_{\rm C}k_{\rm C}[u_{\rm C}^{-}e^{ik_{\xi}d} - u_{\rm C}^{+}e^{-ik_{\xi}d}] = 0, \tag{A2}
$$

where $d = d_A + d_B + d_C$ is the total thickness of the entire structure.

Regarding the interfaces between two elastically different materials, stress σ and displacement u should be continuous across the interfaces. At the A/B interface, the continuous displacement, $u_A(z = d_A, t) = u_B(z = d_A, t)$, gives

$$
u_{A}^{+}e^{-ik_{A}d_{A}} + u_{A}^{-}e^{ik_{A}d_{A}} = u_{B}^{+}e^{-ik_{B}d_{A}} + u_{B}^{-}e^{ik_{B}d_{A}}, \quad (A3)
$$

and the continuous stress, $\sigma_A(z = d_A, t) = \sigma_B(z = d_A, t)$, gives

$$
c_A k_A [u_A^- e^{ik_A z} - u_A^+ e^{-ik_A z}] = c_B k_B [u_B^- e^{ik_B z} - u_B^+ e^{-ik_B z}].
$$
\n(A4)

Similarly, the continuous displacement at the B/C interface, $u_B(z = d_A + d_B, t) = u_C(z = d_A + d_B, t)$, gives

$$
u_{\rm B}^{+}e^{-ik_{\rm B}(d_{\rm A}+d_{\rm B})} + u_{\rm B}^{-}e^{ik_{\rm B}(d_{\rm A}+d_{\rm B})} = u_{\rm C}^{+}e^{-ik_{\rm C}(d_{\rm A}+d_{\rm B})} + u_{\rm C}^{-}e^{ik_{\rm C}(d_{\rm A}+d_{\rm B})},\tag{A5}
$$

and the continuous stress, $\sigma_B(z = d_A + d_B, t) = \sigma_C$ $(z = d_A + d_B, t)$, gives

$$
c_{\rm B}k_{\rm B}[u_{\rm B}^{-}e^{ik_{\rm B}(d_{\rm A}+d_{\rm B})}-u_{\rm B}^{+}e^{-ik_{\rm B}(d_{\rm A}+d_{\rm B})}]
$$

= $c_{\rm C}k_{\rm C}[u_{\rm C}^{-}e^{ik_{\rm C}(d_{\rm A}+d_{\rm B})}-u_{\rm C}^{+}e^{-ik_{\rm C}(d_{\rm A}+d_{\rm B})}].$ (A6)

Equations $(A1)$ – $(A6)$ form a system of linear equations with u_{ξ}^{+} and u_{ξ}^{-} being six variables to be solved, and the corresponding coefficient matrix is given by

 $\sqrt{2}$ ⎜ ⎜ ⎜ ⎜ ⎜ ⎜ ⎝ $1 \t -1 \t 0 \t 0 \t 0 \t 0$ $e^{-ik_A d_A}$ $e^{ik_A d_A}$ $-e^{-ik_B d_A}$ $-e^{ik_B d_A}$ 0 0 $c_A k_A e^{-ik_A d_A} -c_A k_A e^{ik_A d_A} -c_B k_B e^{-ik_B d_A}$ $c_B k_B e^{ik_B d_A}$ 0 0 0 $e^{-ik_B(d_A + d_B)}$ $e^{ik_B(d_A + d_B)}$ $-e^{-ik_C(d_A + d_B)}$ $-e^{ik_C(d_A + d_B)}$ $-e^{ik_C(d_A + d_B)}$ 0 $c_B k_B e^{-ik_B(d_A + d_B)} -c_B k_B e^{ik_B(d_A + d_B)} -c_C k_C e^{-ik_C(d_A + d_B)} c_C k_C e^{ik_C(d_A + d_B)}$ 0 0 0 0 e^{-ik_Cd} − e^{ik_Cd} ⎞ $\begin{array}{c} \hline \end{array}$.

To obtain a nontrivial solution to the linear-equation system, the determinant of this matrix should be equal to 0, which gives

$$
c_{\rm ACC}(-1 + e^{2id_{\rm A}\omega/v_{\rm A}})(-1 + e^{2id_{\rm B}\omega/v_{\rm B}})(-1 + e^{2id_{\rm C}\omega/v_{\rm C}})v_{\rm B}^2
$$

+ $c_{\rm B}^2(1 + e^{2id_{\rm A}\omega/v_{\rm A}})(-1 + e^{2id_{\rm B}\omega/v_{\rm B}})(1 + e^{2id_{\rm C}\omega/v_{\rm C}})$
× $v_{\rm A}v_{\rm C} + c_{\rm B}c_{\rm C}(1 + e^{2id_{\rm A}\omega/v_{\rm A}})(1 + e^{2id_{\rm B}\omega/v_{\rm B}})$
× $(-1 + e^{2id_{\rm C}\omega/v_{\rm C}})v_{\rm A}v_{\rm B} + c_{\rm A}c_{\rm B}(-1 + e^{2id_{\rm A}\omega/v_{\rm A}})$
× $(1 + e^{2id_{\rm B}\omega/v_{\rm B}})(1 + e^{2id_{\rm C}\omega/v_{\rm C}})v_{\rm B}v_{\rm C} = 0$, (A7)

where all wave numbers k_{ξ} are replaced by ω/v_{ξ} .

APPENDIX B: EXPRESSIONS OF Ω AND A IN THE **ANALYTICAL FORMULA OF THE DISPERSION RELATION OF THE EXCHANGE MAGNON**

Assume the magnetization at the initial equilibrium state is (m_x^0, m_y^0, m_z^0) , the expressions of Ω and Λ are given by

$$
\Omega = (\Psi_{23} - \Psi_{32})m_x^0 + (\Psi_{31} - \Psi_{13})m_y^0 + (\Psi_{12} - \Psi_{21})m_z^0
$$
\n(B1)

and

Г

$$
\Lambda = \Psi_{23}\Psi_{32} + \Psi_{31}\Psi_{13} + \Psi_{12}\Psi_{21},
$$
 (B2)

where

$$
\Psi_{12} = H_z^{\text{bias}} - M_s m_z^0 - \frac{2K_1}{\mu_0 M_s} (3m_y^{0^2} m_z^0 - m_z^{0^3}), \qquad (B3)
$$

$$
\Psi_{13} = -H_{y}^{\text{bias}} - M_{\text{s}} m_{y}^{0} - \frac{2K_{1}}{\mu_{0} M_{\text{s}}} (m_{y}^{0^{3}} - 3m_{y}^{0} m_{z}^{0^{2}}), \quad \text{(B4)}
$$

$$
\Psi_{21} = -H_z^{\text{bias}} + M_s m_z^0 - \frac{2K_1}{\mu_0 M_s} (m_z^{0^3} - 3m_z^0 m_x^{0^2}), \quad (B5)
$$

$$
\Psi_{23} = H_x^{\text{bias}} + M_s m_x^0 - \frac{2K_1}{\mu_0 M_s} (3m_z^{02} m_x^0 - m_x^{03}), \qquad (B6)
$$

$$
\Psi_{31} = H_{\mathcal{Y}}^{\text{bias}} - \frac{2K_1}{\mu_0 M_s} (3m_x^{0^2} m_y^0 - m_y^{0^3}), \tag{B7}
$$

$$
\Psi_{32} = -H_x^{\text{bias}} - \frac{2K_1}{\mu_0 M_s} (m_x^{0^3} - 3m_x^0 m_y^{0^2}), \tag{B8}
$$

with K_1 being the magnetocrystalline anisotropy coefficient. The magnon dispersion relationship, $\omega_m(k_m)$, is obtained analytically from the linearization of the LLG

FIG. 7. (a) Distribution of strain, ε_{zz} , in the *x*-*z* cross section of the freestanding Pt/MAFO(001)/SiN multilayer at $t = 54$ ps after strain injection, and (b) enlarged section of the dashed rectangles in (a). Freestanding multilayer is integrated on Si substrate with an air cavity at its surface. (c) Distribution of magnetization change, Δm_x , in *x*-*z* cross section of the MAFO layer at $t = 54$ ps after laser-pulse excitation, and (d) enlarged section of the dashed rectangles in (c). All physical quantities are assumed to be uniform along the *y* axis.

equation under zero magnetic damping $(\alpha = 0)$. Detailed procedures can be found in our previous work [\[15\]](#page-16-14).

APPENDIX C: ACOUSTIC EXCITATION OF MAGNONS IN THE 2D MULTIPHASE SYSTEM

The laser-induced acoustic pulse injection is assumed to be uniform on the Pt top surface. As shown in Fig. $7(a)$, strain ε_{zz} is almost uniform along the *x* axis after the standing acoustic wave forms inside Pt/MAFO(001)/SiN. As a result, the acoustically excited magnons, $\Delta m_x(\mathbf{r}, t)$ $(\mathbf{r} = x, y, z)$, are also almost uniform along the *x* axis, as shown in Fig. $7(c)$. Near the stress-free lateral surfaces of the Pt and MAFO layers, an acoustic wave with mechanical displacement u_x is produced and propagates along the *x* axis due to the time-varying tension (positive ε_{zz}) and compression (negative ε_{zz}) along the *z* axis from strain injection. This induces a nonuniform in-plane strain, ε_{xx} , and hence, ε_{zz} in the region across which acoustic wave u_x propagates, as shown in Fig. $7(b)$. Accordingly, the distribution of magnons, Δm_x (**r**, *t*), is also nonuniform near the lateral surfaces of Pt and MAFO, as shown in Fig. $7(d)$. However, the standing acoustic waves and the excited magnons in most regions of the membrane are uniform along the *x* axis. This is because in MAFO with an in-plane size of 1×1 mm² for example, ε_{xx} can only travel for about 20 μm in 2 ns from the lateral surfaces of MAFO towards its center, even if we use a high longitudinal sound speed of 9462 m s⁻¹ (the same as that in SiN). This means that the phonons and magnons in 92% $[=(1 \text{ mm} - 0.02 \text{ mm} \times 2)^2/1 \text{ mm}^2]$ of the area should still be uniform in the *x*-*y* plane in 2 ns.

The simulation results above were obtained by discretizing the entire heterostructure (including the freestanding multilayer, air, and the Si substrate) into a 2D system of computational cells. The numbers of computational cells along the *x* and *z* axes are $n_x = 50000$ and $n_z = 93$, respectively. The cell sizes along the *x* and *z* axes are $\Delta x = 1$ nm and $\Delta z = 0.83$ nm, respectively. Starting from the top surface of the simulation system, the top 2 layers of the cells $(2\Delta z)$ are designated as free space. The following Pt and MAFO layers are discretized into 8 layers and 15 layers of computational cells along the *z* axis, respectively. Next, the following 38 layers of the computational cells are all designated as SiN. In the last 30 layers of the computational cells, the bottom 20 layers are all designated as the Si substrate and the remaining 10 layers are designated as either Si or air, as shown in Fig. $7(a)$, which makes the SiN bottom surface stress-free and enables it to reflect the acoustic wave. The air below the SiN, Pt, and MAFO layers is all discretized into 40 000 computational cells along the *x* axis.

In the 2D simulations above, the dynamics of the EM waves [Eqs. (5) and (6)], and hence, the induced eddy current [Eq. [\(7\)\]](#page-4-3) are not considered. The LLG equation [Eq. [\(2\)\]](#page-3-1) and the elastodynamic equation [Eq. [\(4\)\]](#page-4-4) are solved in a coupled fashion with a real-time step of $\Delta t = 2 \times 10^{-15}$ s. For the boundary conditions of the elastodynamics in the 2D system, $\sigma_{ix} = 0$ ($i = x, y, z$) is applied on the stressfree lateral surfaces of the Pt and MAFO layers, and $\sigma_{iz} = 0$ is applied on the stress-free top surface of the Pt layer. To model the injection of a ps-duration acoustic pulse, a Gaussian-shaped stress pulse, $\sigma_{zz}(z = d_{\text{MAPO}} + d_{\text{Pt}},$ t) = $\sigma_{\text{max}} \exp[-t^2/2\tau^2]$, is applied at the top surface of the Pt layer at $t = 0$ ps, where $\sigma_{\text{max}} = 3$ GPa and $\tau = 1.5$ ps are the same as those used in Fig. [3.](#page-5-1) The absorbing boundary condition, $\partial u_i / \partial z = -(1/v)(\partial u_i / \partial t)$ (*i* = *x*, *y*, *z*), is applied at the bottom surface of the Si substrate to make it a perfect sink for acoustic waves. Here, *v* is the transverse sound velocity in Si for u_x and u_y and the longitudinal sound velocity for *uz*. The magnetic boundary condition, ∂**m**/∂**n** = 0 [\[63\]](#page-18-4), is applied on all surfaces of the MAFO layer, where **n** is the unit vector normal to the surface. The physical validity of our in-house 2D elastodynamic solver is demonstrated by a benchmarking test against the results obtained from COMSOL Multiphysics, as shown in Fig. [8.](#page-12-0)

APPENDIX D: DERIVATION OF THE INTERFACIAL SPIN CURRENT DENSITY AND THE RESULTING ISHE CHARGE-CURRENT DENSITY

Equation [\(8\)](#page-4-0) can be expanded into

$$
\mathbf{e}_{n} \cdot \mathbf{J}^{s,0} = [0, 0, +1] \cdot \begin{bmatrix} J_{xx}^{s,0} & J_{xy}^{s,0} & J_{xz}^{s,0} \\ J_{yx}^{s,0} & J_{yy}^{s,0} & J_{yz}^{s,0} \\ J_{zx}^{s,0} & J_{zy}^{s,0} & J_{zz}^{s,0} \end{bmatrix}
$$

$$
= [J_{zx}^{s,0}, J_{zy}^{s,0}, J_{zz}^{s,0}],
$$

FIG. 8. Comparison between the simulations from COMSOL Multiphysics and our in-house solver in temporal evolution of the out-of-plane strain, ε_{zz} ; in-plane strain, ε_{xx} ; and in-plane stress, σ_{xx} , at the cell illustrated by the dot (in the middle layer of the MAFO film, 10 nm away from the edge) in the inset strain distribution [which is a section of Fig. [7\(b\)\]](#page-11-2).

$$
= \frac{\hbar}{4\pi} G_{\text{eff}}^{\uparrow\downarrow} \left[\left(m_y \frac{\partial m_z}{\partial t} - m_z \frac{\partial m_y}{\partial t} \right), \left(m_z \frac{\partial m_x}{\partial t} - m_y \frac{\partial m_x}{\partial t} \right) \right] \cdot \left(m_z \frac{\partial m_z}{\partial t} - m_y \frac{\partial m_x}{\partial t} \right) \right].
$$
\n(D1)

Since $J_x^{\text{ISHE}}(z, t) = -\theta_{\text{Pt}}(2e/\hbar)J_{zy}^{\text{s}}(z, t), J_y^{\text{ISHE}}(z, t) = \theta_{\text{Pt}}$ $(2e/\hbar)J_{zx}^s(z,t)$, and $J_z^{\text{ISHE}}(z,t) = 0$, one can further write

$$
\begin{bmatrix} J_{x}^{\text{ISHE},0} \\ J_{y}^{\text{ISHE},0} \\ J_{z}^{\text{ISHE},0} \end{bmatrix} = \begin{bmatrix} \frac{\theta_{\text{Pt}} G_{\text{eff}}^{\uparrow \downarrow} e}{2\pi} \left(m_{x} \frac{\partial m_{z}}{\partial t} - m_{z} \frac{\partial m_{x}}{\partial t} \right) \\ \frac{\theta_{\text{Pt}} G_{\text{eff}}^{\uparrow \downarrow} e}{2\pi} \left(m_{y} \frac{\partial m_{z}}{\partial t} - m_{z} \frac{\partial m_{y}}{\partial t} \right) \\ 0 \end{bmatrix}, \quad (D2)
$$

where **m** and ∂**m**/∂*t* are based on the time-varying magnetization at the MAFO/Pt interface. If omitting damping, one can write under the plane-wave assumption that

$$
m_i = m_i^{\text{eq}} + \Delta m_i; \ \Delta m_i = |\Delta m_i^0|e^{i(kz - \omega t)}, \ i = x, y, z,
$$
\n(D3)

for a specific magnon mode, or $\Delta m_i(z, t) = |\Delta m_i^0| \cos(kz - t)$ ωt) in the real-space and time domain, where *k* is the wave number and $|\Delta m_i^0|$ is the peak amplitude of magnetizationcomponent variation. $m_i^{\dot{eq}}$ are the normalized magnetization components at initial equilibrium, with

$$
(m_x^{\text{eq}}, m_y^{\text{eq}}, m_z^{\text{eq}}) = \left(\frac{1}{2}, \frac{1}{2}, \frac{\sqrt{2}}{2}\right)
$$

FIG. 9. Evolution of filtered $J_x^{\text{ISHE},0}$ resulting from the 154-GHz $m = 1$ mode magnon [orange, contributing to total J_x^c in Fig. $3(e)$] and the 240-GHz $m = 1$ magnon mode [blue, corresponding to total J_x^c in Fig. [4\(d\)\]](#page-6-0). In the filtering process, a third-order bandpass filter, with a bandwidth of 5 GHz, was employed to isolate the frequency components near 154 GHz (i.e., from 151.5 to 156.5 GHz) and near 240 GHz (i.e., from 237.5 to 242.5 GHz) from time-domain data. These two frequency ranges were carefully chosen to capture the target signal while minimizing extraneous frequency interference. Zero-phase technique was also applied to maintain the temporal integrity of the original signal.

herein. Plugging Eq. [\(D3\)](#page-12-1) into Eq. [\(D2\),](#page-12-2) $J_i^{\text{ISHE},0}$ can be further written as

$$
\begin{bmatrix}\nJ_x^{\text{ISHE},0} \\
J_y^{\text{ISHE},0} \\
J_z^{\text{ISHE},0}\n\end{bmatrix} \\
= \begin{bmatrix}\n\frac{\theta_{\text{Pt}} G_{\text{eff}}^{\uparrow \downarrow} e}{2\pi} (m_x^{\text{eq}} |\Delta m_x^0| - m_z^{\text{eq}} |\Delta m_x^0|) \omega \sin(kz - \omega t) \\
\frac{\theta_{\text{Pt}} G_{\text{eff}}^{\uparrow \downarrow} e}{2\pi} (m_y^{\text{eq}} |\Delta m_z^0| - m_z^{\text{eq}} |\Delta m_y^0|) \omega \sin(kz - \omega t) \\
0\n\end{bmatrix}.
$$
\n(D4)

Thus, the peak magnitude of $J_i^{\text{ISHE},0}$ depends not only on $|\Delta m_i^0|$ but also the angular frequency, ω . Based on the simulated $\Delta m_i(z = d_{\text{MAFO}}, t)$, we extract $(|\Delta m_x^0|, |\Delta m_y^0|, |\Delta m_z^0|) = (0.085, 0.0849, 0.0693)$ for the 154-GHz $m = 1$ mode magnon [corresponding to Fig. [3\(c\)\]](#page-5-1) and $(|\Delta m_x^0|, |\Delta m_y^0|, |\Delta m_z^0|) = (0.0672, 0.0669, 0.0546)$ for the 240-GHz $m=1$ magnon mode [corresponding to Fig. [4\(d\)\]](#page-6-0). Based on Eq. [\(D4\),](#page-12-3) one can predict, for example, the peak magnitude of $J_x^{\text{ISHE},0}$ resulting from the 240-GHz $m = 1$ magnon mode is about 1.24 times larger than that from the 154-GHz $m = 1$ magnon mode. This is consistent with the ratio of 1.22 obtained from the time-domain profile of the filtered $J_x^{\text{ISHE},0}$ data, as shown by Fig. [9.](#page-12-4) It is noteworthy that the 240-GHz ISHE charge-current density has a larger peak amplitude than its 154-GHz counterpart but faster attenuation.

APPENDIX E: A LIST OF MATERIAL PARAMETERS USED IN ANALYTICAL CALCULATIONS AND DYNAMICAL PHASE-FIELD SIMULATIONS

The following parameters for MAFO(001) are taken from Refs. [\[29](#page-17-5)[,64\]](#page-18-5), including the Gilbert damping coefficient, $\alpha^0 = 0.0015$, for the $m = 0$ magnon mode; mass density, $\rho = 4355 \text{ kg m}^{-3}$; gyromagnetic ratio, $\gamma = 0.227$ rad MHz A⁻¹ m; saturation magnetization, M_s = 0.0955 MA m−1; magnetocrystalline anisotropy coefficient, $K_1 = -477.5$ Jm⁻³; and magnetoelastic coupling coefficients, $B_1 = 1.2$ MJ m⁻³ and $B_2 = 0$ [\[29\]](#page-17-5). The elastic stiffness coefficients of MAFO, $c_{11} = 282.9$ GPa, c_{12} = 155.4 GPa, and c_{44} = 154.8 GPa, are assumed to be the same as those of MgAl₂O₄ [\[65\]](#page-18-6), while the exchange coupling coefficient, $A_{ex}=4$ pJ m⁻¹, is assumed to be same as that of $CoFe₂O₄$ [\[39\]](#page-17-16).

For SiN, *c*11= 283.81 GPa, *c*12= 110.37 GPa, and c_{44} = 86.72 GPa are calculated using a Young's modulus of 222 GPa and Poisson's ratio of 0.28 [\[66\]](#page-18-7) by assuming isotropic elasticity, which is appropriate for an amorphous solid. The mass density is $\rho = 3170 \text{ kg m}^{-3}$.

For Si [\[67\]](#page-18-8), which is incorporated as the supporting substrate in the 2D simulations (see Appendix [C\)](#page-11-0), *c*11= 167.4 GPa, *c*12= 65.2 GPa, *c*44= 79.6 GPa, and $\rho = 2330 \text{ kg m}^{-3}$.

For Pt [\[68\]](#page-18-9), *c*11= 347 GPa, *c*12= 250 GPa, *c*44= 75 GPa, and $\rho = 21 450 \text{ kg m}^{-3}$. The plasma frequency, $\omega_p = 9.1 \text{ rad}$ fs⁻¹, and electron relaxation time, $\tau_e = 7.5$ fs, are taken from Ref. [\[69\]](#page-18-10).

Acoustic attenuation data for MAFO is not yet available, so the phenomenological stiffness damping coefficients, β , of all materials are assumed to be same as that of the Si substrate, with $\beta = 4.48 \times 10^{-15}$ s, which is comparable to the value previously extracted for $Ga_3Gd_5O_{12}(001)$ single crystals [\[16\]](#page-16-15). The value of β for Si was obtained by fitting the experimentally determined attenuation coefficient, $\lambda = 9$ cm⁻¹, of a 7.2-GHz transverse acoustic wave in Si [\[67\]](#page-18-8) to an analytical formula, $\beta = 2k\lambda/(\omega(k^2 - \lambda^2))$ [\[16\]](#page-16-15), where $\omega = 2\pi \times 7.2$ GHz and $k = \omega/v$ are the angular frequency and angular wave number, respectively; and $v = 5090 \text{ m s}^{-1}$ is the longitudinal speed of sound in Si [\[67\]](#page-18-8). From the formula for β(*k*), we calculate λ for other frequencies and wave numbers, which enables the analytical calculation of the lifetime of the acoustic phonon modes, $\tau_{ph} = 1/(\lambda v)$. The relative permittivity, ε_r , is assumed to be 1 for all materials.

APPENDIX F: NUMERICAL METHODS FOR SOLVING THE COUPLED LLG, ELASTODYNAMIC, AND MAXWELL'S EQUATIONS

For the simulations of Figs. $3-5$, the system is discretized into a 1D grid of computational cells along the *z* axis, with a cell size of $\Delta z = 0.83$ $\Delta z = 0.83$ nm (in Figs. 3 and [4\)](#page-6-0) or $\Delta z = 0.3$ nm (in Fig. [5\)](#page-8-0). Equations [\(2\)](#page-3-1)[–\(7\)](#page-4-3) are solved simultaneously with a real-time step of $\Delta t = 2 \times 10^{-18}$ s. When solving the equations, the central finite-difference method is used to numerically calculate the spatial derivatives and the classical Runge-Kutta method is used for time marching.

When solving the LLG equation [Eq. (2)], the magnetic boundary condition ∂**m**/∂**n** = 0 [\[63\]](#page-18-4) is applied on all surfaces of MAFO, where **n** is the unit vector normal to the surface. When solving the elastodynamic equation [Eq. [\(4\)\]](#page-4-4), the continuity of mechanical displacement **u** and stress σ are applied at any interface between two elastically different materials. The boundary condition of continuous stress at the Pt top surface and the SiN bottom surface becomes the stress-free boundary condition, since stress *σ* in the free space is 0, specifically, $σ_{iz} = 0$ ($i = x, y, z$). As mentioned in the main text, the injection of the ps bulk acoustic pulse, $\varepsilon_{zz}(z,t)$, is simulated by applying timevarying stress $\sigma_{zz}(t)$ (time-dependent boundary condition) at the top surface of the Pt layer. Note that the applied stress, $\sigma_{zz}(t)$, converges to 0 over the course of time, which enables the top surface of the Pt layer to be stressfree again after injection of the ps acoustic pulse. For the substrate-supported Pt/MAFO/SiN multilayer (the control simulation), the absorbing boundary condition, $\partial u_i/\partial z =$ $-(1/v)(\partial u_i/\partial t)$ ($i = x, y, z$), is applied at the top surface of the SiN layer to make it a perfect sink for acoustic waves. Here, v is the transverse sound velocity for u_x and u_v and the longitudinal sound velocity for u_z .

Maxwell's equations [Eqs. (5) and (6)] are solved using the conventional finite-difference time-domain method. In the 1D system, the absorbing boundary condition, $\partial \mathbf{E}^{EM}/\partial z = -(1/c)(\partial \mathbf{E}^{EM}/\partial t)$ [\[70\]](#page-18-11), is applied on both the bottom and top surfaces of the computational system to prevent the emitted EM waves from being reflected to the system, where *c* is light speed in the free space.

APPENDIX G: TEMPORAL PROFILES OF THE *m* **= 1 MODE MAGNON EXTRACTED FROM Fig. [3\(c\)](#page-5-1)**

Using inverse Fourier transform (similarly to the procedures in Fig. [9\)](#page-12-4), we extract the temporal profiles of the $m = 1$ mode magnon in both the freestanding and substrate-supported multilayers, as shown in Fig. [10.](#page-14-3)

APPENDIX H: TEMPORAL PROFILES OF JISHE(*t***) and Jp(***t***) AT THE Pt/MAFO INTERFACE CORRESPONDING TO J^c (***t***) IN Fig. [3\(e\)](#page-5-1)**

The polarization (eddy) current, $J^p(t)$, has a 180° phase difference from $J^{\text{ISHE}}(t)$ and is not negligible, as shown in Fig. [11.](#page-14-4) As a result, the amplitude of $\mathbf{J}^{\mathbf{c}}(t) = \mathbf{J}^{\text{ISHE}}(t) + \mathbf{J}^{\text{p}}(t)$ is smaller than that of $\mathbf{J}^{\text{ISHE}}(t)$.

FIG. 10. Evolution of extracted magnetization variation, $\Delta m_x(t)$, for the $m=1$ magnon mode in the freestanding Pt/MAFO/SiN multilayer (blue) and substrate-supported (yellow) Pt/MAFO/SiN(substrate, acoustic sink) heterostructure.

APPENDIX I: TEMPORAL PROFILE AND FREQUENCY SPECTRUM OF FREE-SPACE EEM(*t***) CORRESPONDING TO J^c (***t***) IN Fig. [3\(e\)](#page-5-1)**

Both the temporal profile and the frequency spectrum of the emitted electric field, $\mathbf{E}^{\text{EM}}(t)$, are similar to those of $J^c(t)$, as shown in Fig. [12.](#page-14-5)

APPENDIX J: NONLINEAR MAGNON MODES INDUCED BY THE ACOUSTIC PHONON MODES IN Fig. [4\(c\)](#page-6-0)

Under multiple driving standing acoustic phonon modes (up to sixth order) in the freestanding multilayer, the acoustically excited magnon modes display complex frequency mixing and doubling behaviors, as shown in Fig. [13.](#page-14-6)

APPENDIX K: TABULAR DATA RELATED TO Fig. [5](#page-8-0) AND EXTENDED DISCUSSION

In the substrate-supported multilayer, the absorbing boundary condition is applied to the bottom surface of

FIG. 11. Evolution of ISHE charge-current **J**ISHE (in red) and polarization current J^p (in blue) at the Pt/MAFO interface $(z = d_{\text{MAFO}})$ in the freestanding multilayer. Inset shows an enlargement of their evolutions during $t = 300-340$ ps to show the phase difference between them.

FIG. 12. (a) Evolution of electric field component $E_x^{\text{EM}}(t)$ of the EM wave in free space or, more specifically, at 4 nm above the Pt top surface $(z = d_{\text{MAFO}} + d_{\text{Pt}} + 4 \text{ nm})$, which are emitted from the freestanding (blue) and substrate-supported (red) Pt/MAFO/SiN multilayers. (b) Frequency spectra of $E_x^{\text{EM}}(t)$ data.

the SiN layer to make SiN a perfect acoustic sink. The dominant magnon mode in the freestanding multilayer has the same frequency as the driving standing acoustic phonon mode (f_n) , while the dominant magnon mode in the substrate-supported multilayer has the same frequency as the $m = 1$ mode exchange magnon $(f_{m=1})$. Under the exact resonant magnon-phonon condition, one has $f_n = f_{m-1}$. As

FIG. 13. Frequency spectra of (top) strain, $\varepsilon_{zz}(t)$; (middle) magnon component, $\Delta m_x(t)$; and (bottom) total charge-current density, $J_x^c(t)$, at the Pt/MAFO interface, where the vertical axes are plotted on a log scale. Time-domain data of $\varepsilon_{zz}(t)$ and $J_x^c(t)$ are shown in Figs. $4(b)$ and $4(d)$.

shown in Table [I,](#page-7-0) in some cases, there is a small discrepancy between f_n and $f_{m=1}$ because (i) d_{MAFO} and d_{SiN} used in numerical simulations cannot exactly match those predicted analytically via Eq. (1) ; and (ii) there is an unavoidable numerical error in the discrete Fourier transform. Here, both frequency f and linewidth Δf are extracted from the frequency spectra of the time-domain ISHE charge-current density, $J_x^{\text{ISHE}}(t)$, data, rather than total $J_x^c(t) = J_x^{\text{ISHE}}(t) + J_x^{\text{P}}(t)$ at the MAFO/Pt interface. Our tests have shown that Q extracted from the frequency spectra of $J_x^{\text{ISHE}}(t)$ and $J_x^{\text{c}}(t)$ are almost the same. $J_x^{\text{ISHE}}(t)$ can be acquired from coupled phonon-magnon dynamics simulations, while obtaining $J_x^c(t)$ requires the use of coupled phonon-magnon-photon dynamics simulations that are computationally more expensive.

APPENDIX L: INFLUENCE OF ELASTIC DAMPING AND MAGNETIC DAMPING ON THE QUALITY FACTOR OF THE FREESTANDING MULTILAYER

As shown in Fig. $14(a)$, turning OFF either type of damping enhances both the amplitude and the lifetime of J_x^c . A longer lifetime results in an increase in the quality factor (*Q*). Moreover, turning OFF magnetic damping (gray curve) leads to a larger peak amplitude for J_x^c than the case of turning OFF elastic damping (green curve). This is reasonable because J_x^c results from the spin current density, and hence, the magnetization amplitude, at the MAFO/Pt interface. However, turning OFF elastic damping (green curve) leads to an even longer lifetime, which should lead to a larger *Q*. This expectation is consistent with the frequency spectra in Fig. [14\(b\),](#page-15-2) which show that the green curve (zero elastic damping) has the narrowest linewidth, and thus, the largest *Q*.

In our numerical simulations, the layer thickness must be equal to $N\Delta z$, where $\Delta z = 0.83$ nm is the cell size, and the integer number N is the number of cells. Under the present thickness setup (see Fig. [14](#page-15-2) caption), the frequencies of the $n = 2$ mode acoustic phonon and $m = 1$ mode exchange magnon are 153.8 and 154.407 GHz, respectively, which are calculated analytically via Eq. [\(1\)](#page-2-0) in the main paper. As shown in Fig. $14(b)$, when the magnetic damping is ON (green and blue curves), the $m = 1$ mode exchange magnon will decay and vanish. The dominant magnon mode in the freestanding multilayer is the "acoustic" magnon mode, which is excited by an acoustic pulse via magnetoelastic coupling and, therefore, has the same frequency as the driving $n = 2$ mode acoustic phonon (the simulated peak at 153.75 GHz agrees very well with the analytical calculation). When the magnetic damping is OFF (gray curve), the $m = 1$ mode exchange magnon, with a peak at 154.4 GHz (which is again almost the same as that of the analytically calculated value), is

FIG. 14. (a) Evolution of total charge current $J_{\rm{v}}^{\rm{c}}(t)$ at the Pt/MAFO interface in a freestanding
mm/MAFO(12.45 nm)/SiN(31.54 nm) multilayer. $Pt(6.64 \, nm)/MAFO(12.45 \, nm)/SiN(31.54$ $t = 0$ ns is the moment the acoustic pulse was injected from the top surface of the Pt film. (b) Frequency spectra obtained by Fourier transform of time-domain $J_x^c(t)$ data from $t = 0-4$ ns. Blue curve, both magnetic and elastic damping are turned on $(\alpha \neq 0, \beta \neq 0)$, with $Q = 154.6$; gray curve, zero magnetic damping $(\alpha = 0, \beta \neq 0)$, with $Q = 428.1$; green curve, zero elastic damping ($\alpha \neq 0$, $\beta = 0$), with $Q = 588.0$.

significantly amplified and becomes the dominant magnon mode instead.

APPENDIX M: MODELING THE FORMATION OF THz MAGNON POLARONS

The thicknesses of the Pt, MAFO, and SiN films are set as 6.6, 5.9, and 18.1 nm, respectively, to enable formation of the $n = 6$ mode phonon and the $m = 1$ mode magnon, which have the same frequency of 682.8 GHz. Meanwhile, the phonon and the magnon have almost the same spatial profiles in the MAFO film [as shown in Fig. $15(a)$], leading to the same wave number for the two waves and the formation of a magnon polaron. The formation of the magnon polaron is demonstrated by the two frequency peaks (678 and 688 GHz) split from that at 682.8 GHz in the spectra of both the magnon and phonon [as shown in Fig. $15(e)$]. In this simulation, the free parameters in $\sigma_{zz}(t)$ (see Sec. [IV\)](#page-3-2) are $\sigma_{\text{max}} = 3$ MPa and $\tau = 0.5$ ps, which lead to a frequency window covering up to 800 GHz and a peak amplitude of 8.5×10^{-6} in the strain pulse, $\varepsilon_{zz}(t)$, in Pt. The effective magnetic damping, α , and the stiffness damping coefficients, β , are both set to 0, and a scaledup magnetoelastic coupling coefficient, $B_1 = 25B_1^0$, is used to enhance the magnon-phonon coupling strength, where $B_1^0 = 1.2$ MJ m⁻³ is the value given in Appendix [E.](#page-13-0)

FIG. 15. (a) Numerically extracted spatial profiles of the $n = 6$ mode (blue) standing phonon mode, ε_{zz} , in the Pt(6.6 nm)/MAFO(5.9 nm)/SiN(18.1 nm) freestanding multilayer and the $m = 1$ mode (black) magnon, Δm_x , in the MAFO film. Spatial profiles are extracted by performing inverse Fourier transform of the 682.8-GHz peaks in their own frequency spectra with the backaction of Δm on ε_{zz} being turned OFF. ε_{zz} and Δm_x have approximately the same spatial profile in the MAFO film. Evolution of (b) strain, $\varepsilon_{zz}(t)$, and (c) magnetization change, $\Delta m_x(t)$, at the Pt/MAFO interface. $t = 0$ is the moment the acoustic pulse is injected from the top surface of the Pt film. Frequency spectra of both $\varepsilon_{zz}(t)$ and $\Delta m_x(t)$ in (d) 0–700 GHz, and (e) 670–700 GHz.

- [1] P. Pirro, V. I. Vasyuchka, A. A. Serga, and B. Hillebrands, [Advances in coherent magnonics,](https://doi.org/10.1038/s41578-021-00332-w) Nat. Rev. Mater. **6**, 1114 (2021).
- [2] B. Lenk, H. Ulrichs, F. Garbs, and M. Münzenberg, The building blocks of magnonics, Phys. Rep. **507**[, 107 \(2011\).](https://doi.org/10.1016/j.physrep.2011.06.003)
- [3] A. Kimel, *et al.*[, The 2022 magneto-optics roadmap,](https://doi.org/10.1088/1361-6463/ac8da0) J. Phys. D: Appl. Phys. **55**, 463003 (2022).
- [4] I. Razdolski, A. Alekhin, N. Ilin, J. P. Meyburg, V. Roddatis, D. Diesing, U. Bovensiepen, and A. Melnikov, Nanoscale interface confinement of ultrafast spin transfer [torque driving non-uniform spin dynamics,](https://doi.org/10.1038/ncomms15007) Nat. Commun. **8**, 15007 (2017).
- [5] L. Brandt, U. Ritzmann, N. Liebing, M. Ribow, I. Razdolski, P. Brouwer, A. Melnikov, and G. Woltersdorf, Effective exchange interaction for terahertz spin waves in iron layers, Phys. Rev. B **104**[, 94415 \(2021\).](https://doi.org/10.1103/PhysRevB.104.094415)
- [6] R. Salikhov, I. Ilyakov, L. Körber, A. Kákay, R. A. Gallardo, A. Ponomaryov, J.-C. Deinert, T. V. A. G. de Oliveira, K. Lenz, J. Fassbender, S. Bonetti, O. Hellwig, J. Lindner, and S. Kovalev, Coupling of terahertz light with manometre-wavelength magnon modes via spin–orbit torque, Nat. Phys. **19**[, 529 \(2023\).](https://doi.org/10.1038/s41567-022-01908-1)
- [7] V. S. Vlasov, A. V. Golov, L. N. Kotov, V. I. Shcheglov, A. M. Lomonosov, and V. V. Temnov, The modern problems

[of ultrafast magnetoacoustics \(review\),](https://doi.org/10.1134/S1063771022010079) Acoust. Phys. **68**, 18 (2022).

- [8] S. Zhuang, P. B. Meisenheimer, J. Heron, and J.-M. Hu, A narrowband spintronic terahertz emitter based on magnetoelastic heterostructures, [ACS Appl. Mater. Interfaces](https://doi.org/10.1021/acsami.1c13461) **13**, 48997 (2021).
- [9] Y. Li, C. Zhao, W. Zhang, A. Hoffmann, and V. Novosad, Advances in coherent coupling between magnons and acoustic phonons, APL Mater. **9**[, 60902 \(2021\).](https://doi.org/10.1063/5.0047054)
- [10] M. Bombeck, A. S. Salasyuk, B. A. Glavin, A. V. Scherbakov, C. Brüggemann, D. R. Yakovlev, V. F. Sapega, X. Liu, J. K. Furdyna, A. V. Akimov, and M. Bayer, Excitation of spin waves in ferromagnetic (Ga, Mn)As layers by picosecond strain pulses, Phys. Rev. B **85**[, 195324 \(2012\).](https://doi.org/10.1103/PhysRevB.85.195324)
- [11] L. Thevenard, E. Peronne, C. Gourdon, C. Testelin, M. Cubukcu, E. Charron, S. Vincent, A. Lemaître, and B. Perrin, Effect of picosecond strain pulses on thin layers of the [ferromagnetic semiconductor](https://doi.org/10.1103/PhysRevB.82.104422) (Ga, Mn)(As, P), Phys. Rev. B **82**, 104422 (2010).
- [12] A. Ghita, T.-G. Mocioi, A. M. Lomonosov, J. Kim, O. Kovalenko, P. Vavassori, and V. V. Temnov, Anatomy of ultrafast quantitative magnetoacoustics in freestanding nickel thin films, Phys. Rev. B **107**[, 134419 \(2023\).](https://doi.org/10.1103/PhysRevB.107.134419)
- [13] T.-G. Mocioi, A. Ghita, and V. V. Temnov, Towards resonantly enhanced acoustic phonon-exchange magnon [interactions at THz frequencies,](https://doi.org/10.3390/magnetochemistry9070184) Magnetochemistry **9**, 184 (2023).
- [14] U. Vernik, A. M. Lomonosov, V. S. Vlasov, L. N. Kotov, D. A. Kuzmin, I. V. Bychkov, P. Vavassori, and V. V. Temnov, Resonant phonon-magnon interactions in freestanding [metal-ferromagnet multilayer structures,](https://doi.org/10.1103/PhysRevB.106.144420) Phys. Rev. B **106**, 144420 (2022).
- [15] S. Zhuang and J. M. Hu, Excitation and detection of coherent sub-terahertz magnons in ferromagnetic and anti[ferromagnetic heterostructures,](https://doi.org/10.1038/s41524-022-00851-2) Npj Comput. Mater. **8**, 167 (2022).
- [16] S. Zhuang and J.-M. Hu, Acoustic attenuation in magnetic [insulator films: Effects of magnon polaron formation,](https://doi.org/10.1088/1361-6463/acae30) J. Phys. D: Appl. Phys. **56**, 54004 (2023).
- [17] J. Xu, C. Zhong, X. Zhou, X. Han, D. Jin, S. K. Gray, L. Jiang, and X. Zhang, Coherent pulse echo in hybrid [magnonics with multimode phonons,](https://doi.org/10.1103/PhysRevApplied.16.024009) Phys. Rev. Appl. **16**, 24009 (2021).
- [18] K. An, A. N. Litvinenko, R. Kohno, A. A. Fuad, V. V. Naletov, L. Vila, U. Ebels, G. de Loubens, H. Hurdequint, N. Beaulieu, J. Ben Youssef, N. Vukadinovic, G. E. W. Bauer, A. N. Slavin, V. S. Tiberkevich, and O. Klein, Coherent long-range transfer of angular momentum between magnon Kittel modes by phonons, Phys. Rev. B **101**[, 60407 \(2020\).](https://doi.org/10.1103/PhysRevB.101.060407)
- [19] A Papp, W. Porod, and G. Csaba, Nanoscale neural network [using non-linear spin-wave interference,](https://doi.org/10.1038/s41467-021-26711-z) Nat. Commun. **12**, 6422 (2021).
- [20] O. Wang, A. V. Chumak, and P. Pirro, Inverse-design magnonic devices, [Nat. Commun.](https://doi.org/10.1038/s41467-021-22897-4) **12**, 2636 (2021).
- [21] G. Tas and H. J. Maris, Electron diffusion in metals studied by picosecond ultrasonics, Phys. Rev. B **49**[, 15046 \(1994\).](https://doi.org/10.1103/PhysRevB.49.15046)
- [22] A. V. Scherbakov, A. S. Salasyuk, A. V. Akimov, X. Liu, M. Bombeck, C. Brüggemann, D. R. Yakovlev, V. F. Sapega, J. K. Furdyna, and M. Bayer, Coherent magnetization precession in ferromagnetic (Ga, Mn)As induced by picosecond acoustic pulses, Phys. Rev. Lett. **105**[, 117204 \(2010\).](https://doi.org/10.1103/PhysRevLett.105.117204)
- [23] J. V. Jäger, A. V. Scherbakov, T. L. Linnik, D. R. Yakovlev, M. Wang, P. Wadley, V. Holy, S. A. Cavill, A. V. Akimov, A. W. Rushforth, and M. Bayer, Picosecond inverse mag[netostriction in galfenol thin films,](https://doi.org/10.1063/1.4816014) Appl. Phys. Lett. **103**, 32409 (2013).
- [24] D. Sri Gyan, D. Mannix, D. Carbone, J. L. Sumpter, S. Geprägs, M. Dietlein, R. Gross, A. Jurgilaitis, V.-T. Pham, H. Coudert-Alteirac, J. Larsson, D. Haskel, J. Strempfer, and P. G. Evans, Low-temperature nanoscale heat transport in a gadolinium iron garnet heterostructure probed by ultrafast x-ray diffraction, Struct. Dyn. **9**[, 45101 \(2022\).](https://doi.org/10.1063/4.0000154)
- [25] O. Mosendz, V. Vlaminck, J. E. Pearson, F. Y. Fradin, G. E. W. Bauer, S. D. Bader, and A. Hoffmann, Detection and quantification of inverse spin Hall effect from spin pump[ing in permalloy/normal metal bilayers,](https://doi.org/10.1103/PhysRevB.82.214403) Phys. Rev. B **82**, 214403 (2010).
- [26] M. A. Wahada, E. Şaşıoğlu, W. Hoppe, X. Zhou, H. Deniz, R. Rouzegar, T. Kampfrath, I. Mertig, S. S. P. Parkin, and G. Woltersdorf, Atomic scale control of spin current transmission at interfaces, Nano Lett. **22**[, 3539 \(2022\).](https://doi.org/10.1021/acs.nanolett.1c04358)
- [27] D. Turan, P. K. Lu, N. T. Yardimci, Z. Liu, L. Luo, J.-M. Park, U. Nandi, J. Wang, S. Preu, and M. Jarrahi, Wavelength conversion through plasmon-coupled surface states, [Nat. Commun.](https://doi.org/10.1038/s41467-021-24957-1) **12**, 4641 (2021).
- [28] T. Nan, Y. Lee, S. Zhuang, Z. Hu, J. D. Clarkson, X. Wang, C. Ko, H. Choe, Z. Chen, D. Budil, J. Wu, S. Salahuddin, J. Hu, R. Ramesh, and N. Sun, Electric-field control of spin [dynamics during magnetic phase transitions,](https://doi.org/10.1126/sciadv.abd2613) Sci. Adv. **6**, eabd2613 (2020).
- [29] S. Emori, D. Yi, S. Crossley, J. J. Wisser, P. P. Balakrishnan, B. Khodadadi, P. Shafer, C. Klewe, A. T. N'Diaye, B. T. Urwin, K. Mahalingam, B. M. Howe, H. Y. Hwang, E. Arenholz, and Y. Suzuki, Ultralow damping in nanometer[thick epitaxial spinel ferrite thin films,](https://doi.org/10.1021/acs.nanolett.8b01261) Nano Lett. **18**, 4273 (2018).
- [30] P. Li, L. J. Riddiford, C. Bi, J. J. Wisser, X.-Q. Sun, A. Vailionis, M. J. Veit, A. Altman, X. Li, M. D. C. S, X. Wang, Y. Suzuki, and S. Emori, Charge-spin interconversion in epitaxial Pt probed by spin-orbit torques in a magnetic insulator, [Phys. Rev. Mater.](https://doi.org/10.1103/PhysRevMaterials.5.064404) **5**, 64404 (2021).
- [31] C. Liu, *et al.*, Long-distance propagation of shortwavelength spin waves, [Nat. Commun.](https://doi.org/10.1038/s41467-018-03199-8) **9**, 738 (2018).
- [32] P. Hansen, in *Physics of Magnetic Garnets*, edited by A. Paoletti (1978), pp. 56–133.
- [33] S. Crossley, A. Quindeau, A. G. Swartz, E. R. Rosenberg, L. Beran, C. O. Avci, Y. Hikita, C. A. Ross, and H. Y. Hwang, Ferromagnetic resonance of perpendicularly magnetized Tm₃Fe₅O₁₂/Pt heterostructures, Appl. Phys. Lett. **115**, 172402 (2019).
- [34] See the Supplemental Material at http://link.aps.org/supple [mental/10.1103/PhysRevApplied.21.044009](http://link.aps.org/supplemental/10.1103/PhysRevApplied.21.044009) for a list of symbols for the main physical quantities.
- [35] Y. Tserkovnyak, A. Brataas, and G. E. W. Bauer, Spin pumping and magnetization dynamics in metallic multilayers, Phys. Rev. B **66**[, 224403 \(2002\).](https://doi.org/10.1103/PhysRevB.66.224403)
- [36] A. G. Gurevich and G. A. Melkov, *Magnetization Oscillations and Waves* (CRC Press, London, 2020).
- [37] T. Henighan, *et al.*, Generation mechanism of terahertz [coherent acoustic phonons in Fe,](https://doi.org/10.1103/PhysRevB.93.220301) Phys. Rev. B **93**, 220301 (2016).
- [38] V. V. Temnov, C. Klieber, K. A. Nelson, T. Thomay, V. Knittel, A. Leitenstorfer, D. Makarov, M. Albrecht, and R. Bratschitsch, Femtosecond nonlinear ultrasonics in gold [probed with ultrashort surface plasmons,](https://doi.org/10.1038/ncomms2480) Nat. Commun. **4**, 1468 (2013).
- [39] A. V. Azovtsev and N. A. Pertsev, Dynamical spin phenomena generated by longitudinal elastic waves traversing CoFe2O4 [films and heterostructures,](https://doi.org/10.1103/PhysRevB.100.224405) Phys. Rev. B **100**, 224405 (2019).
- [40] A. V. Azovtsev, A. I. Nikitchenko, and N. A. Pertsev, Energy-efficient spin injector into semiconductors driven by elastic waves, [Phys. Rev. Mater.](https://doi.org/10.1103/PhysRevMaterials.5.054601) **5**, 54601 (2021).
- [41] A. V. Azovtsev and N. A. Pertsev, Acoustically excited magnetic dynamics and spin flow in spin-valve structures, [Phys. Rev. Appl.](https://doi.org/10.1103/PhysRevApplied.17.034070) **17**, 34070 (2022).
- [42] K. Uchida, J. Xiao, H. Adachi, J. Ohe, S. Takahashi, J. Ieda, T. Ota, Y. Kajiwara, H. Umezawa, H. Kawai, G. E. W. Bauer, S. Maekawa, and E. Saitoh, Spin Seebeck insulator, Nat. Mater. **9**[, 894 \(2010\).](https://doi.org/10.1038/nmat2856)
- [43] K. Uchida, H. Adachi, T. An, T. Ota, M. Toda, B. Hillebrands, S. Maekawa, and E. Saitoh, Long-range spin See[beck effect and acoustic spin pumping,](https://doi.org/10.1038/nmat3099) Nat. Mater. **10**, 737 (2011).
- [44] S. A. Bender and Y. Tserkovnyak, Interfacial spin and heat [transfer between metals and magnetic insulators,](https://doi.org/10.1103/PhysRevB.91.140402) Phys. Rev. B **91**, 140402 (2015).
- [45] J. Xiao, G. E. W. Bauer, K. Uchida, E. Saitoh, and S. Maekawa, Theory of magnon-driven spin Seebeck effect, Phys. Rev. B **81**[, 214418 \(2010\).](https://doi.org/10.1103/PhysRevB.81.214418)
- [46] J. Kimling, G.-M. Choi, J. T. Brangham, T. Matalla-Wagner, T. Huebner, T. Kuschel, F. Yang, and D. G. Cahill, [Picosecond spin Seebeck effect,](https://doi.org/10.1103/PhysRevLett.118.057201) Phys. Rev. Lett. **118**, 57201 (2017).
- [47] T. J. Huisman, R. V. Mikhaylovskiy, J. D. Costa, F. Freimuth, E. Paz, J. Ventura, P. P. Freitas, S. Blügel, Y. Mokrousov, T. Rasing, and A. V. Kimel, Femtosecond control of electric currents in metallic ferromagnetic heterostructures, [Nat. Nanotechnol.](https://doi.org/10.1038/nnano.2015.331) **11**, 455 (2016).
- [48] M. Li, T. Hao, W. Li, and Y. Dai, Tutorial on optoelectronic oscillators, APL Photonics **6**[, 61101 \(2021\).](https://doi.org/10.1063/5.0050311)
- [49] T. Hao, Y. Liu, J. Tang, Q. Cen, W. Li, N. Zhu, Y. Dai, J. Capmany, J. Yao, and M. Li, Recent advances [in optoelectronic oscillators,](https://doi.org/10.1117/1.AP.2.4.044001) Adv. Photonics **2**, 44001 (2020).
- [50] F. Zou, L. Zou, B. Yang, Q. Ma, X. Zou, J. Zou, S. Chen, D. Milosevic, Z. Cao, and H. Liu, Optoelectronic oscillator for [5G wireless networks and beyond,](https://doi.org/10.1088/1361-6463/ac13f2) J. Phys. D: Appl. Phys. **54**, 423002 (2021).
- [51] L. Maleki, in *2012 European Frequency and Time Forum* (2012), pp. 497–500.
- [52] D. H. Auston, K. P. Cheung, and P. R. Smith, Picosec[ond photoconducting Hertzian dipoles,](https://doi.org/10.1063/1.95174) Appl. Phys. Lett. **45**, 284 (1984).
- [53] M. B. Ketchen, D. Grischkowsky, T. C. Chen, C. Chi, I. N. Duling, N. J. Halas, J. Halbout, J. A. Kash, and G. P. Li, Generation of subpicosecond electrical pulses on coplanar transmission lines, [Appl. Phys. Lett.](https://doi.org/10.1063/1.96709) **48**, 751 (1986).
- [54] Z. Feng, H. Qiu, D. Wang, C. Zhang, S. Sun, B. Jin, and W. [Tan, Spintronic terahertz emitter,](https://doi.org/10.1063/5.0037937) J. Appl. Phys. **129**, 10901 (2021).
- [55] C. Bull, S. M. Hewett, R. Ji, C.-H. Lin, T. Thomson, D. M. Graham, and P. W. Nutter, Spintronic terahertz emitters: [Status and prospects from a materials perspective,](https://doi.org/10.1063/5.0057511) APL Mater. **9**, 90701 (2021).
- [56] E. T. Papaioannou and R. Beigang, THz spintronic emitters: A review on achievements and future challenges, [Nanophotonics](https://doi.org/10.1515/nanoph-2020-0563) **10**, 1243 (2021).
- [57] T. S. Seifert, L. Cheng, Z. Wei, T. Kampfrath, and J. Qi, Spintronic sources of ultrashort terahertz electromagnetic pulses, [Appl. Phys. Lett.](https://doi.org/10.1063/5.0080357) **120**, 180401 (2022).
- [58] K. Neeraj, *et al.*, Inertial spin dynamics in ferromagnets, Nat. Phys. **17**[, 245 \(2021\).](https://doi.org/10.1038/s41567-020-01040-y)
- [59] V. Unikandanunni, R. Medapalli, M. Asa, E. Albisetti, D. Petti, R. Bertacco, E. E. Fullerton, and S. Bonetti, Iner[tial spin dynamics in epitaxial cobalt films,](https://doi.org/10.1103/PhysRevLett.129.237201) Phys. Rev. Lett. **129**, 237201 (2022).
- [60] A. M. Lomonosov, V. V. Temnov, and J.-E. Wegrowe, Anatomy of inertial magnons in ferromagnetic nanostructures, Phys. Rev. B **104**[, 54425 \(2021\).](https://doi.org/10.1103/PhysRevB.104.054425)
- [61] R. Mondal, L. Rózsa, M. Farle, P. M. Oppeneer, U. Nowak, and M. Cherkasskii, Inertial effects in ultrafast spin dynamics, [J. Magn. Magn. Mater.](https://doi.org/10.1016/j.jmmm.2023.170830) **579**, 170830 (2023).
- [62] H.-J. Song and N. Lee, Terahertz communications: Challenges in the next decade, [IEEE Trans. Terahertz Sci.](https://doi.org/10.1109/TTHZ.2021.3128677) Technol. **12**, 105 (2022).
- [63] V. V. Kruglyak, O. Y. Gorobets, Y. I. Gorobets, and A. N. Kuchko, Magnetization boundary conditions at a ferromag[netic interface of finite thickness,](https://doi.org/10.1088/0953-8984/26/40/406001) J. Phys.: Condens. Matter **26**, 406001 (2014).
- [64] K. B. Modi, M. C. Chhantbar, and H. H. Joshi, Study of [elastic behaviour of magnesium ferri aluminates,](https://doi.org/10.1016/j.ceramint.2005.01.005) Ceram. Int. **32**, 111 (2006).
- [65] A. Yoneda, Pressure derivatives of elastic constants of single crystal MgO and MgAl₂O₄, J. Phys. Earth 38, 19 (1990).
- [66] J. J. Vlassak and W. D. Nix, A new bulge test technique for the determination of Young's modulus and Poisson's ratio of thin films, J. Mater. Res. **7**[, 3242 \(1992\).](https://doi.org/10.1557/JMR.1992.3242)
- [67] D. Li and D. G. Cahill, Attenuation of 7 GHz surface acoustic waves on silicon, Phys. Rev. B **94**[, 104306 \(2016\).](https://doi.org/10.1103/PhysRevB.94.104306)
- [68] S. M. Collard and R. B. McLellan, High-temperature elastic [constants of platinum single crystals,](https://doi.org/10.1016/0956-7151(92)90011-3) Acta Metall. Mater. **40**, 699 (1992).
- [69] C. L. Foiles, in *Electrical Resistivity, Thermoelectrical Power and Optical Properties*, edited by K.-H. Hellwege [and J. L. Olsen \(Springer-Verlag Berlin Heidelberg, 1985\),](https://doi.org/10.1007/10201705_12) pp. 212–222.
- [70] J.-M. Jin, *Theory and Computation of Electromagnetic Fields* (John Wiley & Sons, Inc., Hoboken, New Jersey, Canada, 2015).